

GE Mobile Communications

M-PD PLUS PERSONAL RADIO SYSTEM (806-870 MHz)

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SERVICE SECTION LBI-38125

Maintenance Manual

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SPECIFICATIONS

SYSTEM

FCC Identification Number AXA9WNTR-157-A2

Frequency Range

Transmit: 806-870 MHz
Receive: 851-870 MHz

Frequency Stability 5 PPM 2.5 PPM

Battery Drain (at 7.5 Vdc)

Standby: 105 milliamperes Receive (rated audio): 230 milliamperes

Transmitter: 2.0 amperes

Battery Life

800 mAh: 4.3 hours at 5-5-90 duty cycle

1200 mAh: 6.7 hours at 5-5-90 duty cycle

Dimensions with 800 mAh battery

($H \times W \times D$): 183 x 68.7 x 42.5 mm (7.2 x 2.7 x 1.7

inches)

Weight with 800 mAh battery 24 ounces

Temperature Range

Operating: $-30 \text{ to } +60^{\circ}\text{C} (-22 \text{ to } +140^{\circ}\text{F})$

RF Power Output 1 to 3 Watts

Spurious Emissions -16 dBm

Maximum Deviation 5 kHz

FM Hum & Noise (EIA) -40 dB

Audio Distortion 3% (60% Modulation)

Frequency Stability 2.5 PPM (-30 to +60oC)

RF Load Impedance 50 ohms

Microphone Sensitivity Less than 90 dB SPL (EIA 60% MOD)

SPECIFICATIONS (CONTINUED)

Maximum Attack Time 25 milliseconds (PTT pushed)

Audio Frequency Response Within +2 and -8 dB of a 6 dB/octave

pre-emphasis from 300 Hz to 3000 Hz

RECEIVE

Sensitivity (12 dB SINAD) -116 dBm

Spurious Emissions -57 dBm

Spurious Response 72 dBm (minimum)

Rejection (EIA) 70 dB

Selectivity (EIA) 67 dB (25 kHz)

Squelch Sensitivity 6 dB SINAD

Distortion (EIA 0.5 watt) 5%

Audio Frequency Response Within +1 and -3 dB of a 6 dB/octave

de-emphasis from 300 Hz to 3000 Hz

OPTIONS AND ACCESSORIES



COMBINATION NOMENCLATURE

DIGITS 1 & 2	DIGIT 3	DIGIT 4	DIGIT 5	DIGIT 6	DIGIT 7
Product Code	Frequency	Controller	Selectivity	Stability	Power Source
PD	806-870 MHz	T System	S Standard	2 2.5 ppm	N NiCd 800 MAH
					NiCd 1200 MAH
					No Battery

DESCRIPTION

The GE M-PD 16 PLUS Personal Radio is a high-quality, high-performance FM radio. The radio is synthesized and operates in both trunked and conventional communication systems. The trunked mode allows selection of either a communications group or and individual radio within a system. Both the selected group and the individual radio are secured through digital signaling.

In the conventional mode, the user selects a channel and directly communicates on that channel. A channel is a transmit/receive radio frequency pair.

A group consists of several users with a common group identification (ID). A radio may have several groups, but the selected group determines who the unit can call at any specific time. In the trunked mode, a set of groups which communicate on a set of channels is called a system. In the conventional mode, a system is a set of channels. A system may consist of all trunking groups and channels, all conventional channels, or a mixture of both.

The M-PD 16 PLUS Personal Radio is designed to operate in a 16 PLUS Digital Trunking System or as a conventional radio providing the following features.

In trunked mode:

- Programmable Multiple System Capability -- The radio can operate on different trunked sites or on different systems at the same site.
- Multiple Group Capability -- The radio can communicate on several Groups within one trunked system.
- Group Call -- The M-PD 16^{PLUS} has the capability of simultaneously calling all units within a group.
- Programmable Carrier Control Timer -Personality information includes an optional period of transmit time from 15
 to 120 seconds. After the timer expires,
 the unit will automatically unkey and
 provide an alerting tone. This feature is
 re-initiated on every PTT and the alert
 tone is removed upon release of the PTT.

- Minimum Volume Level -- Personality information includes a minimum volume level.
- Programmable Squelch -- The noise squelch opening threshold can be programmed for each channel.
- Receive Mode Lock Out -- In normal trunked operation, the radio will not transmit while in the receive mode.
- Automatic Power Levels -- The desired power level on each channel can be programmed into the radio personality.
 Power level is automatically selected dependent on the channel.
- Emergency Feature -- An emergency group can be programmed into the radio. This group is selected by pressing the EMER button. This allows a user to quickly reach this group and initiate the 16^{PLUB} emergency signalling.
- Simple Remote Control Capability -- A speaker/microphone (which can also control PTT and the volume level) can be connected through the UDC (Universal Device Connector).
- Surveillance Feature -- The display backlighting may be programmed on or off per group. The side-tone beep, related to the operation of the radio controls, is also capable of being disabled on a group-by-group basis.
- Pushbutton Controls -- All control functions on the radio, with the exception of the power switch, are operated through pushbuttons.
- Programmable through UDC -- The entire personality of the radio is programmed through four connections of the UDC.
- Eight-Character Alphanumeric Liquid Crystal Display -- This display is used to exhibit the condition of the radio. It shows channel designation, Channel Guard or Digital Channel Guard on/off,

transmit mode, volume level, battery condition, channel busy, and high/low power output.

In conventional mode:

- 48-Channel Capability -- Channel designation can be a mixture of numerics (0-48) and alphanumerics displayed through the LCD. Channel control can come from the up/down channel ramping button, the emergency channel feature, or the front keypad.
- Programmable Multi-Tone Channel Guard (CTCSS) Encode/Decode -- Channel Guard tone frequencies within the range of 67 Hz to 210.7 Hz, including all of the standard EIA frequencies, may be programmed. Different encode/decode, encode only, and with/without Channel Guard frequencies are also programmable into the radio.
- Programmable Multi-Code Digital Channel Guard Encode/Decode -- Similar capability as with Tone Channel Guard is provided.
- Programmable Talkaround Capability The ability to switch the transmit frequency from a repeater frequency to a direct communications frequency.
- Channel-Busy Lock Out -- Personality information includes the capability to prevent the transmitter from operating on a channel where carrier activity is present. The channel busy indicator (BSY) is active during this time.
- Physically an M-PD 16^{PLUS} radio consists of four main printed wire board assemblies and a battery pack as follows:
- a. A printed wire board specially shielded with zinc alloy on which the radio assembly (transmit/receive/synthesizer) is assembled.
- b. A logic system board containing the microprocessor.
- c. A speaker board with audio IC.

- d. A display board carrying various display and indicating circuits.
- e. A battery pack that fits the M-PD main unit.
- f. Lightweight metal front and back housing.

RADIO ASSEMBLY

TRANSMIT CIRCUIT

The transmit circuit consists of four major circuits as follows:

- a. Wide Band Hybrid Exciter -- Amplifies the signal from the frequency synthesizer with about 21 dB gain.
- b. Wide Band Power Amplifier --Amplifies the output signal of the exciter to the desired output level for transmission (a gain of 13 to 18 dB).
- c. Wide Band Power Control Hybrid IC --Can reduce the transmitter output level by 10 dB.
- d. Output Low-pass Filter (LPF) -- Consists of a three stage LPF to eliminate harmonics.

The transmitter completely covers the band within the split. No adjustments are needed except for the rf power control voltage from the controller.

RECEIVE CIRCUIT

The receiver consists of three major circuits as follows:

- a. Front-End Circuit -- Consists of a one stage pre-amplifier (with band-pass filters).
- b. First Mixer and IF circuit -- A special double-balanced mixer is used to convert the incoming signal to 45 MHz first IF. This is put through a band-pass filter (BPF) and an IF amplifier to get the desired first IF signal.
- c. Second IF (455 kHz) -- Consists of one IC and one BPF containing the second mixer, the second IF amplifier, and the

FM detector. The second IF output provides the Logic section with audio output.

FREQUENCY SYNTHESIZER

The frequency synthesizer is made up of three major modules as follows:

- a. VCO Module -- The 800 MHz band frequency synthesizer has one common VCO for both transmitting and receiving. The transmitter is modulated at both the VCO and the VCTCXO.
- b. VCTCXO Module -- The VCTCXO is a voltage controlled, temperature compensated crystal oscillator providing 13.2 MHz as a reference frequency with modulation capability.
- c. Phase-Lock Loop -- Consists of a frequency divider and a low current drain CMOS IC for phase comparison.

LOGIC CIRCUIT

The Logic circuit consists of a system board with an audio IC, a speaker board, and a LCD board as follows:

- a. System Board -- Carries two microprocessors, a battery backed RAM, a ROM, audio circuit and I/O interconnections with the frequency synthesizer and the display. This board commands all the functions and operation of the M-PD 16 PLUS radio.
- b. Audio IC -- Includes transmitter and receiver audio circuits.
- Speaker Board -- Provides an audio processor, operational amplifier, voltage regulator, and a comparator circuit.
- d. LCD Board -- Includes LCD driver circuits for the display.

POWER SUPPLY

The M-PD battery pack connects to the bottom of the M-PD 16 PLUS radio to supply 7.5 Vdc. The battery pack is available in two sizes: 800 mAh and 1200 mAh. Chargers are available in three

different types: a standard 16-hour charger, a rapid charger, and a vehicular charger.

OPERATION

The M-PD $16^{\mbox{\scriptsize PLUS}}$ Personal Radio is delivered disassembled into three parts as follows:

- 1. M-PD Radio (Main Unit)
- 2. Antenna
- 3. Battery Pack

Assemble these parts into one unit according to the following procedure and as shown in Figure 1

NOTE

Either the antenna or the rf connector should be connected to the M-PD radio main unit. If the rf connector is inserted in the receptacle, located on the side of the unit, the antenna connector circuit will open.

- 1. Screw the antenna [2] or the rf test connector [4] in its receptacle. A clockwise turn will insert the antenna or rf test connector, while a counterclockwise turn will remove them.
- 2. Slide the battery pack along the bottom of the M-PD main unit in the arrow-marked direction shown in Figure 1, until the battery locks into place.

OPERATING PROCEDURE

Condensed operating instructions are provided in this manual for used during servicing. Refer to the operator's manual for more detailed instructions.

Sending And Receiving Trunked Messages

When operating in a trunked system (normal operation), use the procedures in this section. Operation in the conventional channel mode is described under Sending And Receiving Conventional Messages.

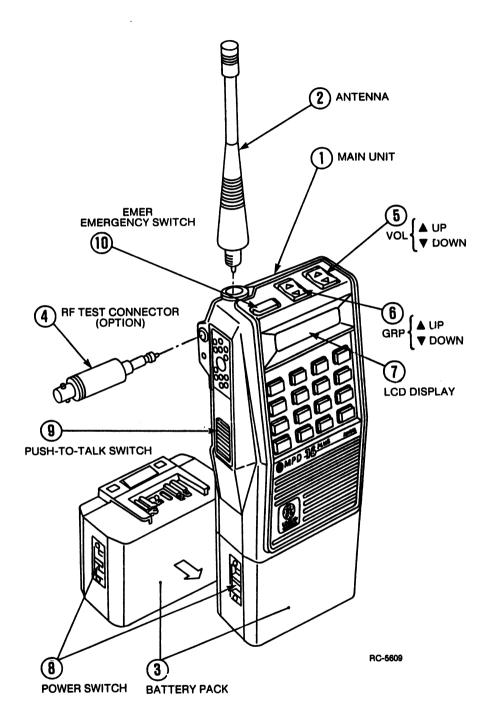


Figure 1 - M-PD 16 CONTROLS AND ACCESSORIES

Receiving A Message

- Slide the on/off switch to the ON position. The alphanumeric display will show CC SCAN until a control channel is found.
- 2. Press the VOL button and listen for the desired level of audio tone.
- Select the trunked System by operating the VOL and GRP buttons.

\mathtt{OR}

Enter the System number through the keypad, followed by the key sequence Shift + 6 (SYS).

4. Select the desired Group by operating the GRP button

OR

Enter the Group number through the keypad, followed by the key sequence Shift + 5 (GRP).

The radio will now receive calls directed to the selected System and Group. If an individual call (call directed only to your radio) is received, the alphanumeric display will show *INDV*.

If a fleet or agency call is received, the alphanumeric display will show FLEET or AGENCY.

Sending A Message

- 1. Slide the on/off switch to the ON position.
- 2. Select the desired System by operating the VOL and GRP buttons.

OR

Enter the System number through the keypad, followed by the key sequence Shift + 6 (SYS).

 Select the desired Group by operating the GRP button.

OF

Enter the Group number through the keypad, followed by the key sequence Shift + 5 (GRP).

- 4. When the BSY indicator is off, press the PTT bar until the TX indicator is continuously displayed and a tone is heard.
- 5. Hold the radio about six inches from your mouth and speak normally.

6. Release the PTT bar when the transmission is complete, and listen for any reply.

Sending And Receiving Conventional Messages

The procedures described here are for operating in a conventional channel mode. Use these procedures if you have a conventional system, or in the event of a failure of the trunked system.

Receiving A Message

- 1. Slide the on/off switch to the ON position.
- 2. Press the VOL button and listen for the desired level of audio tone.
- 3. Select a conventional channel system by operating the VOL and GRP buttons.

OR

Enter the conventional channel system number through the keypad, followed by the key sequence Shift + 6 (SYS).

 Select the desired channel by operating the GRP button.

OR

Enter the channel number through the keypad, followed by the key sequence Shift + 5 (GRP). The radio will now receive messages over the channel.

Sending A Message

NOTE

If you have optional Channel Guard, press the VOL button in its center (disable the squelch) and monitor the channel for activity. DO NOT TRANSMIT UNTIL THE CHANNEL IS CLEAR.

- 1. Slide the on/off switch to the ON position.
- 2. Select a conventional channel system by operating the VOL and GRP buttons.

OR

Enter the conventional channel system number through the keypad, followed by the key sequence Shift + 6 (SYS).

 Select the desired channel by operating the GRP button.

OR

Enter the channel number through the keypad, followed by the key sequence Shift + 5 (GRP).

- 4. Insure that there is no other transmission on the channel (BSY indicator not on).
- 5. Press the PTT bar until the TX indicator is continuously displayed.
- 6. Hold the radio about six inches from your mouth and speak normally.
- 7. Release the PTT bar when the transmission is complete, and listen for any reply.

SPECIAL FEATURES

Alert Tones

Your radio produces audio tones to alert you when the buttons are pressed and at other times during normal operation. The following list of tones are optional and can be programmed off:

- Short tone when a top or front button is pressed.
- Three short tones if PTT bar has been pressed too long and transmitter is about to be turned off.
- Continuous beep tone when PTT bar has been pressed too long and transmitter is turned off.
- Short tone when emergency operation is used.
- Short tone after PTT bar is pressed and radio is ready to transmit.
- Call-queued tone. A high pitched beep signalling the call has been queued and will be placed as soon as a channel is as-

signed.

- System busy. Three low pitched beeps indicating the system is busy.
- Auto-key tone. A long tone if the PTT bar is not pressed when the site equipment assigns a channel. You have up to two seconds to press the PTT bar after the tone to keep the assigned channel.
- A one time boop tone when the battery level is low.
- Burst of several beep tones, if PTT is pressed when battery level is lower than the minimum required voltage level, and the transmitter is disabled.

Carrier Control Timer (Programmable)

Your radio transmitter will turn off if you have pressed the PTT bar for too long a time. A three beep warning tone will be heard if the PTT bar has been pressed too long. If the PTT bar is not released within about five seconds after the warning tone, the radio transmitter will turn off and a continuous beeping will be heard. Release the PTT bar to reset the transmitter and turn off the warning tone. A new call can now be made.

Receiving An Emergency Call

From A Selected System/Group

When you receive an emergency call from the selected Group and System, the *EMER* function indicator and the BSY status flag will come on. The *EMER* function indicator will alternate with the home group display. Follow your standard emergency procedures.

From A Scanned Group

When you receive an emergency call from a scanned Group (scan operating), the display will show the scanned Group display. The *EMER* function indicator will not come on for scanned Groups.

Sending An Emergency Call

To send an Emergency call to the selected System and Group (or optional home group), proceed as follows:

- 1. Press and release the EMER button. The *EMER* function indicator (may be programmed off) and TX status flag will come on. The *EMER* function indicator (if enabled) will alternate with the home group display.
- 2. Press the PTT bar, and speak into the microphone in a normal voice.
- 3. Release the PTT bar when the transmission is completed, and listen for any reply. The TX status flag will go out.

Receiving An Individual Call

When you receive an individual call (call directed only to your radio), the *INDV* function indicator and BSY status flag will be displayed.

If you want to respond to the call, you have up to five seconds to press the PTT bar. Your call will automatically be directed to the station calling you.

Special Call

Sending A Special Call

You may make Special Calls with your radio through the Special Call list. In this method you will scroll through a number of special call names and select the one you wish to call.

- Press and release the SPC button. The alphanumeric display will change from the selected group to one of the last selected special call display. If no special calls are programmed, the display will read NO SPCL.
- 2. Press the GRP button to search (forward or reverse direction) through the Special Call displays. When the desired Special Call name appears on the alphanumeric display, release the GRP button.
- 3. Press the PTT bar and make your call.
- Release the PTT bar when you are done talking, and listen for any reply.
- 5. When the call is finished, press the SPC button. The alphanumeric display will change to the previously selected group.

Telephone Interconnect

You may make telephone calls through the Special Call feature or by direct entry through the keypad.

Using The Special Call Mode

- 1. Press and release the SPC button. The alphanumeric display will change from the selected group to one of the programmed special call displays.
- 2. Press the GRP button to search (forward or reverse) through the displayed list of Special Call names. When the desired telephone interconnect display appears, release the GRP button

OR

Use the keypad to manually enter a star (*) followed by the telephone number. If the number was entered incorrectly, press the CLR function key to delete the incorrect numbers and try again.

OR

Enter the stored number identifier (1 to 10) followed by * through the keypad. Press the RCL key.

- 3. Press and release the PTT bar or SEND function key. You will hear the telephone tones being sent and you will hear ringing. If the call was not placed correctly, press CLR function key and try again.
- 4. When the call is answered, press the PTT bar and wait for the tone before speaking.

NOTE

Unlike a regular telephone, you cannot talk and listen at the same time. Whenever you talk, you can not hear the other party.

- Release PTT bar when you are done talking, and listen for any reply.
- 6. When your call is finished, press the SPC function key to hang up the telephone.

The previously selected Group will appear on the alphanumeric display after about 5 seconds.

Individual Call

Calls may be made to a specific radio by doing the following:

- 1. Press and release the SPC button. The alphanumeric display will change from the selected group to one of the special call displays.
- 2. Press and release one of the GRP buttons until the desired individual call Special Call display appears on the alphanumeric display.
- 3. Enter the radio ID number through the keypad. If the number was entered incorrectly, press the CLR function key to delete the incorrect characters and try again.
- 4. Press the PTT bar and make your call.
- 5. Release the PTT bar when you are done talking, and listen for any reply.
- 6. When the call is finished, press the CLR function key.

Scan

You may program your radio to scan a number of groups or conventional channels for activity. The scan function will not operate when the *EMER* function indicator is on.

Adding To Scan

Set up (or add to) the groups (or channels) to be scanned as follows:

- 1. Press the SCAN button if the SCN status flag is flashing to turn scan off.
- 2. Select the group or channel to be added to Scan using the GRP buttons.
- 3. Press the ADD function key to add the group or channel to scan.

Deleting From Scan

Remove groups (or channels) to be scanned as follows:

- 1. Press the SCAN button if the SCN status flag is flashing to turn scan off.
- 2. Select the group or channel to be removed from Scan using the GRP buttons.
- 3. Press the DEL function key to remove the group or channel from scan.

Priority Scan Feature (Conventional Mode Only)

Priority status may be assigned to a conventional channel already in scan as follows:

- 1. Press the SCAN button if the SCN status flag is flashing to turn off scan.
- 2. Select a conventional channel by operating the GRP button.
- Select the desired channel by operating the GRP button.
- Press the ADD button once to assign priorityone status to the selected channel. A "2" status flag will be displayed next to the SCN flag.

OR

Press the ADD button twice to assign priorityone status to the selected channel A "1" status flag will be displayed next to the SCAN flag.

Starting Or Stopping Scan

- Press the SCAN button to turn on scan. The SCAN status flag will flash.
- 2. Press the SCAN button again to turn off scan. The SCN status flag will stop flashing.

Storing Telephone And Radio ID Numbers

Up to 10, 28-digit telephone numbers or 10 radio IDs may be stored in memory. This feature will save you from entering (and remembering) a telephone or radio ID number. If you make a mistake entering a number, use the CLR function and enter the number again. Store a telephone or radio ID number as follows:

1. Enter the number of the storage location you wish to use.

- 2. Enter the control digit. Use * for storing a phone number or # for storing a radio ID.
- 3. Enter the telephone number or radio ID.

NOTE

If a pause is required between telephone digits (to allow time for switchboard access or other needed delay), use the PAUSE function key when entering the telephone number.

4. Press Shift and STO. The alphanumeric display will show STORED for about two seconds if the number is stored correctly.

Examples:

Store the number 528-7000 in location 4 by entering:

4 * 5 2 8 7 0 0 0 Shift STO

Store the number 1-800-253-7843 in location 2 by entering:

2 * 1 8 0 0 2 5 3 7 8 4 3 Shift STO

Store the number 9-804-847-1800 in location 3, and allow for an outside-line delay after the digit 9 by entering:

3 * 9 Shift PAUSE 8 0 4 8 4 7 1 8 0 0 Shift STO

Sending A Status Message

Your radio may be programmed to send status messages to the dispatcher by entering a status-message code. If the code you entered is not valid, a message will appear in the alphanumeric display. Send a status message as follows:

- 1. Enter the status-message code through the keypad. The entered code will appear in the alphanumeric display.
- 2. Enter the key sequence Shift + 9 (STAT).

Keypad Lock

Your radio may be programmed to allow you to lock or unlock the keypad to prevent accidental

entries. If your radio has been programmed for keypad lock the following will occur:

- Keyboard will be locked when the radio is first turned on.
- The alphanumeric display will show the LOCKED message if a key is pressed when the keypad is locked.
- Pressing the key sequence Shift + 1 (KEY BD) will unlock the keypad and the alphanumeric display will shown the UN-LOCKED message. Enter the key sequence again will lock the keypad.

HI/LO Transmit Power

The transmit power of your radio may be changed from high to low power. Operating on low power will help extend battery operating time. High power will help extend range in fringe areas.

Enter the key sequence Shift + 4 (HI/LO) to change power levels. The HI status flag will be displayed when the radio is transmitting on high power.

SYSTEM ANALYSIS

Refer to Figures 2A and 2B. The M-PD 16^{PLUS} radio consists of four printed wire boards as follows:

- Radio Board -- carries the transmit, receive, and frequency synthesizer circuits.
- System Board -- supports logic control circuits.
- Speaker Board -- provides an audio processor, a voltage regulator, and comparator circuit.
- Display Board -- carries LCD.

Interconnection of the system board with other boards and control circuits is made with flexible circuit boards and connectors.

Circuit illustrations shown are simplified representatives of actual circuits. They are intended only to illustrate basic circuit functions.

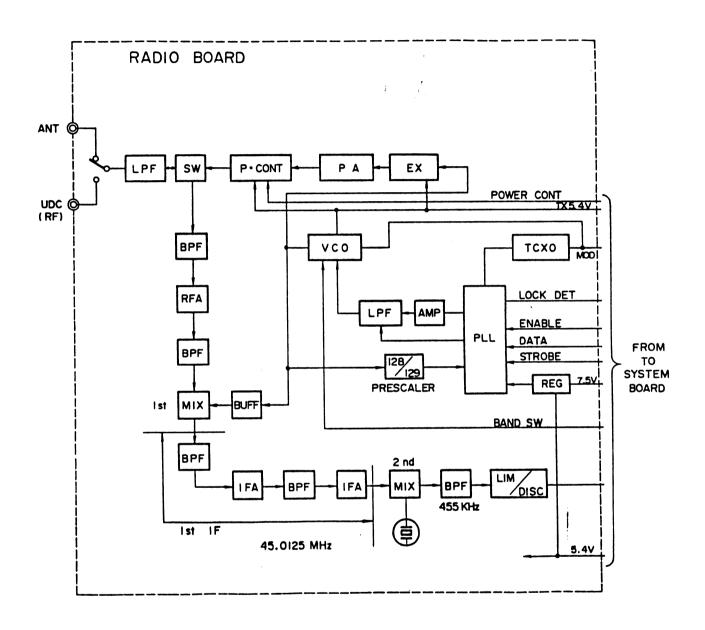
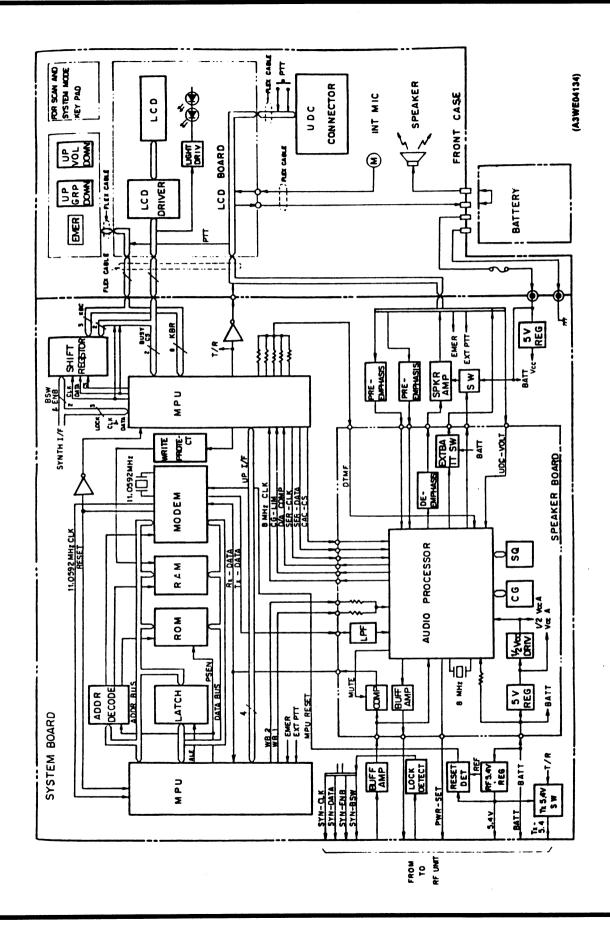


FIGURE 2A - RADIO BLOCK DIAGRAM



RADIO BOARD

TRANSMIT CIRCUITS

The M-PD 16 PLUS transmit circuit, as shown in Figure 2A, consists of the following integrated circuit modules:

- Amplifier (TX-Amp)
- Power Amplifier (PA)
- Power Controller (PC)
- Antenna Switch (AS)
- Filter Network (FN)

Amplifier Module (A201)

Amplifier module (TX-Amp) A201 is a twostage rf amplifier hybrid IC. A 0 dBm rf signal on the input will produce a +23 dBm signal on the output (refer to Figure 3). This module is broadband and does not require turning.

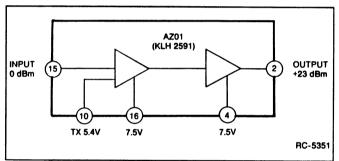


FIGURE 3 - AMPLIFIER MODULE (TX-AMP)

Power Amplifier Module (A202)

Power Amplifier (PA) A202 is a three-stage, wide-band amplifier module with an input and an output impedance of 50 ohms (Figure 4). The first stage of the PA module has the dc power supplied by power control transistor Q202. The rf power output from pin 2 of the TX-Amp module A201 is connected through a resistor attenuator to pin 1 of the PA module where it is applied to the input of the rf power amplifier stages. The rf power amplifier stages amplify the input from the TX-Amp module to a typical power output level of four watts at pin 5. The output at pin 5 is connected through the power control hybrid IC A203 (PC) and filter network FN. A minimum power level of three watts is on the output of the filter network.

Power Control Module (A203)

The rf power output of the radio is regulated by sensing variations in the rf power output of the transmit PA module. These variations are used to control the supply voltage to the first stage of the PA module (Figure 5). Supply voltage cannot be applied to the first stage of the PA module until the transmit circuit is keyed, applying 5.4 volts to pin 11 of Power Control (PC) hybrid IC A203. When the transmit circuit is keyed, the output of a reference amplifier is applied to the positive (+) input of a comparator.

The output of the final PA is connected to pin 1 of the PC module and to the 50 ohm coupled line. The detected voltage on the Control Module coupled output is applied to the negative (-) input of the comparator. The amplifier is enabled when the transmit circuit is keyed, until then, the output of the amplifier is low and transistor Q2O2 is held off. As the PA module begins to increase output power, the detected voltage causes the series regulator circuit to regulate the supply voltage to maintain constant RF output power.

Filter Network (FN)

The output of the PA module is connected to filter network FN through TX-RX switching diode CR201. The FN network is a passive LC low-pass filter with an insertion loss of less than 0.5 dB in the pass-band. If also has a rejection greater than 45 dB in the stop band. The output of the FN is connected to the system antenna or to the UDC connector.

RECEIVE CIRCUIT

The M-PD 16 PLUS receive circuit, as shown in Figure 2A, consists of the following circuits:

- RF Amplifier/Mixer
- First IF Amplifier
- Second IF Amplifier/Discriminator

RF Amplifier/Mixer

The RF Amplifier/Mixer circuit (Figure 6) contains two third-order band-pass filters (FL301 and FL302), and rf amplifier circuit (Q301) and a double-balanced diode mixer circuit (A301). RF from the antenna or UDC connector is coupled through transmit low-pass filter FN and rf switching diode CR201 to the input of the rf amplifier circuit. Low-pass filter FN is used in the receive

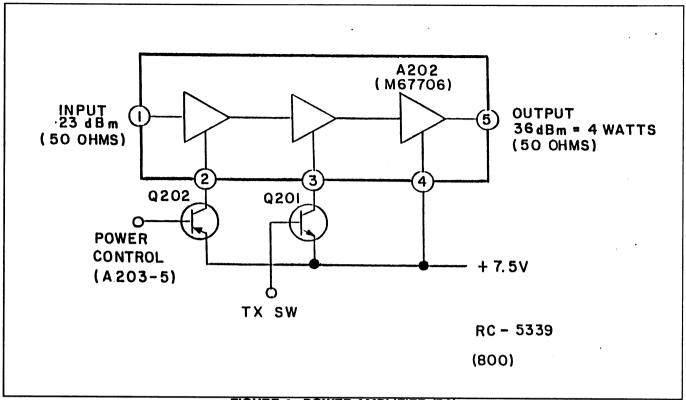


FIGURE 4 - POWER AMPLIFIER (PA)

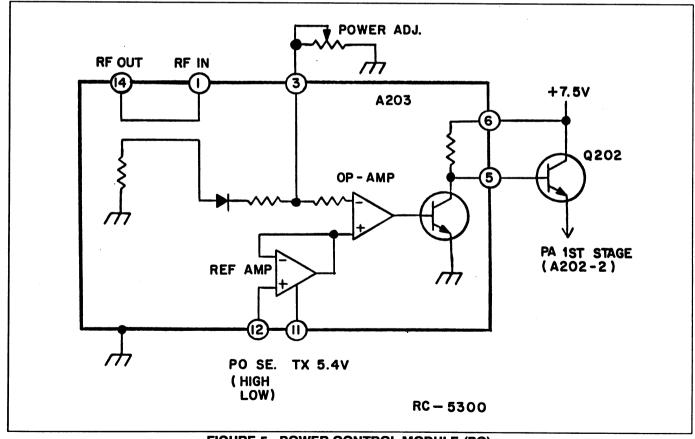


FIGURE 5 - POWER CONTROL MODULE (PC)

circuit to provide additional receive selectivity. The rf signal on the input of the rf amplifier is first coupled through band-pass filter FL301 to the input of grounded emitter, broad-band rf amplifier transistor Q301. This amplifier provides 12 dB of power gain to reduce thermal noise. The output of the rf amplifier is coupled through band-pass filter FL302 to drive double balanced mixer circuit A301.

The rf signal from the rf amplifier and the injection frequency from the synthesizer circuit, provide a 45 MHz IF on the output of the mixer. The double-balanced Mixer has a typical conversion loss of 6 dB between the rf input and IF output. All inputs and the output of the rf Amplifier/Mixer have 50 ohms matching impedance. The +7 dBm injection frequency level, provided by the synthesizer and amplifier circuit transistor Q106, is connected to the injection frequency input through a 50-ohm matching circuit. The output of the Mixer circuit is connected to the input of the first IF Amplifier.

First IF Amplifier

The first IF amplifier contains two amplifier circuits and two crystal filters of two and four poles, respectively (refer to Figure 7). The first IF signal (45 MHz) connects to the input of preamplifier transistor Q302 through pre-crystal filter FL303 with an impedance of approximately 3K ohms. Pre-amplifier Q302 provides a 17 dB power gain. The output is connected to the input of IF amplifier transistor Q303 through crystal filter FL304. IF amplifier Q303 has a 13 dB power gain, an input impedance of approximately 3K ohms, and an output impedance of approximately 2.2K ohms.

Second IF Amplifier/Discriminator (A302)

The Second IF Amplifier/Discriminator circuit (Figure 8) contains FM IF IC A302 (HA12442V) and 455 kHz ceramic filter FL305. The FM IF IC contains a local oscillator, mixer, IF amplifier, FM detector, and an audio amplifier. The 45 MHz IF output from the first IF amplifier is connected to the input of second IF amplifier A302a, pin 2 of HA1244V (1/2) and converted to the second IF frequency (455 kHz). The second IF output is connected to pin 7 input of HA12442V (1/2) through the 455 kHz ceramic filter to the IF amplifier and FM detector circuits. The recovered audio from the FM IF IC is connected to J102-4.

SYNTHESIZER CIRCUIT

The Synthesizer circuit (Figure 9) contains Phase-Lock-Loop (PLL) module A102, VCTCXO Reference Oscillator module A103, TX/RX Voltage Controlled Oscillator (VCO) module A106, and a Low-Pass-Filter (LPF) amplifier. The VCO used to generate the receive and transmit reference frequencies is locked to a stable VCTXCO reference oscillator through a PLL. This feedback loop divides the VCO frequency down to a signal in the range of 7 MHz. This signal is divided with a programmable divider to 5/6.25 kHz, and generates a VCO control signal by comparing the 5/6.25 kHz feedback with a 5/6.25 kHz signal derived by dividing a 13.5 MHz VCTCXO by 1056. As the least-significant bit in the programming is changed, the VCO is forced to change by 5/6.25 kHz.

The synthesizer circuitry is contained on two modules, the VCO module A106 and the VCTCXO reference Oscillator module A103.

Phase-Lock-Loop Module (A102)

The PLL module A 102 contains a reference frequency, divider, phase detector, and a programmable divider. The phase detector dc voltage output signal is filtered with a passive low-pass filter followed by a 6.25 kHz filter to reduce the level of reference modulation on the VCO. This dc output represents the error between the VCO frequency (phase) and the reference (VCTCXO) and is applied to the VCO on frequency. A lock-detect output is developed from pin 9 of A 102. The output is AND with the TX-PTT output from the microcomputer to prevent transmission before the VCO is on frequency.

Serial data from the microcomputer is shifted into the PLL to set the division parameter which establishes the frequency. A clock signal is provided on another input and the data is latched with the enable input.

Voltage-Controlled Oscillator (A106)

The VCO uses a low-noise, high-gain transistor as the basic oscillator. The resonant circuit, which determines the frequency of oscillation, is formed by a high-Q coil which is used to set the center frequency at the factory. The output of the VCO is coupled into a cascade amplifier which produces +3 dBm. The output of the RX-VCO amplifier is coupled into the receive first double-balanced mixer circuit A301 through buffered amplifier

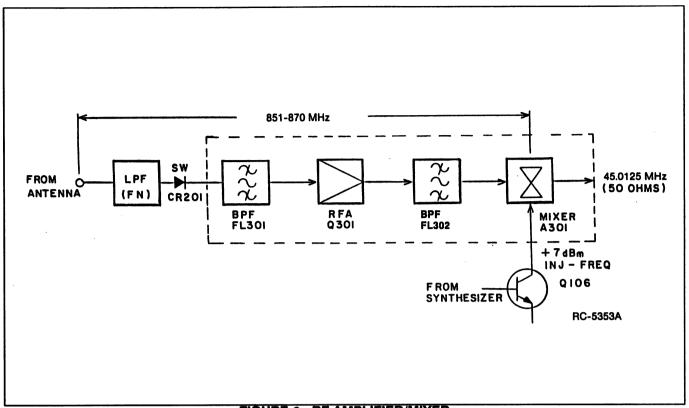
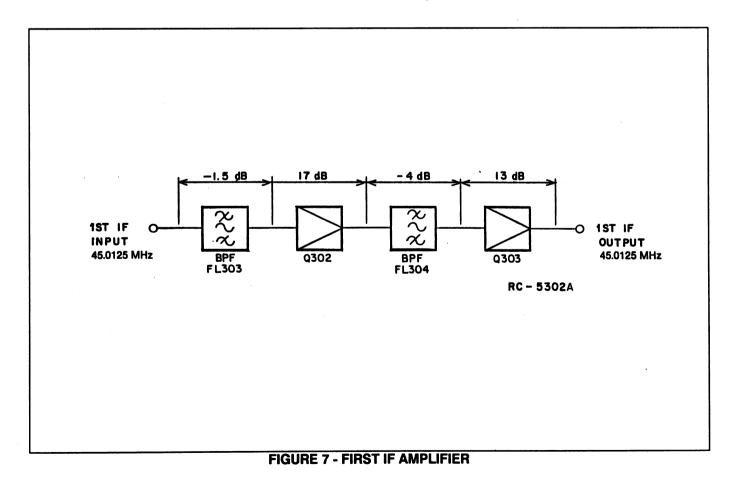


FIGURE 6 - RF AMPLIFIER/MIXER



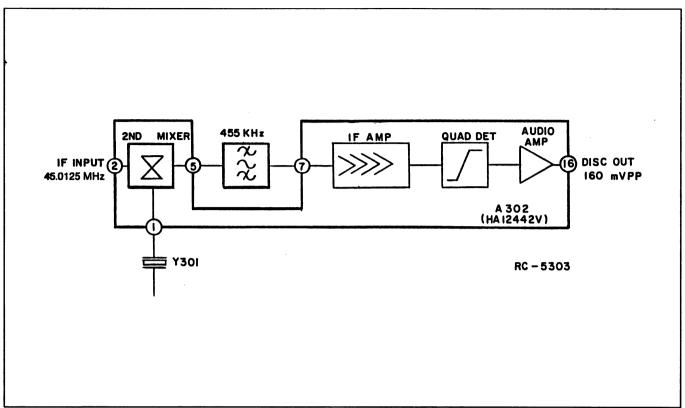


FIGURE 8 - SECOND IF AMPLIFIER/DISCRIMINATOR

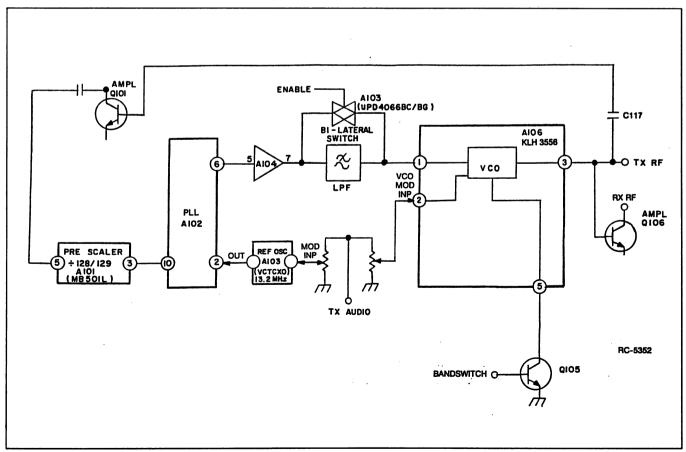


FIGURE 9 - SYNTHESIZER

Q106. The VCO amplifier output is also connected to the input of Tx-Amp transistor Q107.

VCTCXO Reference Oscillator (A103)

The A103 oscillator module is self contained, fully temperature compensated and operates at a frequency of 13.2 MHz. The oscillator also has modulation capability. Frequency is adjusted by a trimmer while monitoring the transmit circuit output at the antenna jack.

CONTROL CIRCUIT

The control circuit consists of control circuits and audio circuits (Figure 2B). Physically, this circuit consists of three circuit boards as follows:

- System Board
- Speaker Board
- LCD Board

System Board

The System board consists of the following circuits (refer to Figure 2):

- CMOS Microcomputer (A1, A7)
- 74HC373 Latch (A2)
- PROM (A3)
- Custom Modem Chip (A4)
- CMOS Logic (A5)
- Shift Register (A6)
- Inverters (A8)
- CMOS RAM (A10) with Lithium Battery BT1
- Operational Amplifiers (All & Al3)
- Audio Amplifier (A15)
- 5.0 Volt Regulator (A17)
- Precision Reference Diode Voltage reference (A18)
- Demultiplexer (A19)

Microcomputer

The main microcomputer circuit in this radio consists of microprocessor 80C31 (A1), Latch (A2), demultiplexer (A19), 32K x 8 EPROM (A3), 8K x 8 RAM (A10), and custom modem IC (A4). This circuitry runs at a 11.0592 MHz rate determined by crystal Y1 and controls the radio through a second microprocessor 637B05 (A7). This microprocessor (A7) runs at an 8 MHz rate. The 8 MHz rate is determined by crystal Y200 located on the Speaker Board. Shift register A6 is also controlled by A7 to provide additional output

pins. Functions of the microcomputer are performed as follows:

- Controlling the modem, ROM and RAM
- Loading data to the frequency synthesizer
- Fetching and processing the PTT, monitor, channel selection, and volume control.
- Loading data to the LCD display
- Controlling the audio circuit (processor)
- Decoding the squelch
- Encoding/decoding the Channel Guard and digital Channel Guard
- Controlling the loading interface for the radio data (channel number and signaling)

Voltage Detector (All, Q13)

IC All and transistor Ql3 are used for the microcomputer reset and RAM data save at voltage drop.

Reset Circuitry (CR5, CR8, A11)

The reset circuitry consists of diodes CR5 and CR8 and part of operational amplifier package All. This circuit generates a reset pulse which is fed into the modem IC (A4) and is passed to microprocessors Al and A7. The modem also contains a watchdog timer in case the processor becomes erratic.

ROM (A3)

IC A3 contains the software to control the microcomputer.

RAM (A10, A5 & BT1, Q5, CR1)

The RAM circuitry consists of RAM IC A10, CMOS logic A5, lithium battery BT1, transistor Q5 and diode package CR1. This RAM circuit has a storage capacity of 8K bits x 8 for storing up to 6K of personality. This personality controls various functions of the radio. The personality data is entered from outside the radio through the UDC connector to the microcomputer and then to the RAM. The data mainly consists of the following:

- Channel Frequency Data
- CG/DCG data
- TX Power, TX Modulation Data
- Squelch Data
- Display Data, etc.

CMOS Logic IC A5 is used to write-protect the RAM to keep the 80C31 microprocessor (A1) from accidently overwriting the stored personality data. Lithium Battery BT1, with diode package CR1 and transistor Q5, maintain this personality when power is turned off.

Modem (A4)

Modem A4 provides high-speed data (9600 baud) encode to the transmitter in the station and the high-speed data decode from the station receiver when used in a trunked system.

CMOS and Latch (A2, A5, A6, and A19)

IC A2 is used as a Data Bus Buffer for the microcomputer. IC A5 is used to write-protect microprocessor A3. Shift register A6 is used to latch the data from the microcomputer for LCD interface. The output signal of IC A19 is used to select the address of A3 and A4, A1 and A10.

Voltage Regulator Circuits

Diode A18 provides a 2.5-volt reference for operational amplifier A11. Operational amplifier A11 transistors Q1, Q2, and Q13 in combination generate 5.4 Vdc for the rf sections (TX and RX). Transistor Q9 and Q14, in conjunction with voltage regulator A17, provide a regulated 5.0 volts dc for the System Board. Transistors Q9 and Q14 limit the current.

External Data Buffer (A8)

The external data buffer is located between the UDC connector and the microcomputer. The buffer converts the level of external signals to match the internal circuits, and protects the internal circuits.

Audio Amplifier (A15)

The audio amplifier is located between the audio processor and the microphone or the speaker. Amplifier A15 amplifies the output signal of the Speaker Board to the level adequate for driving the speaker and UDC audio output.

Speaker Board

The speaker board consists of the following circuits:

• Audio processor (A201)

- Operational Amplifier (A202)
- Voltage Regulator (A203)
- Comparator (A204)

Audio Processor (A201)

The Audio processor consists of a one-chip IC accommodating almost all the audio functions. The audio functions are under control of the microcomputer in compliance with the function of the radio unit. The functions of the audio processor are as follows:

- Tone Reject Filter
- Limiter Amplifier
- Post Limiter Filter
- Squelch Filter and Rectifier
- CG/DCG Encode/Decode Filter and Limiter
- D/A converter and comparator
- OSC Circuit and Digital Interface for Microcomputer

All of these functions are made up of switched capacitor filters, amplifiers, and timing logic. The timing for this logic is derived from the 8.00 MHz clock generator.

Operational Amplifier (A202)

The section of operational amplifier A202 with pins 1, 2, 3 is used to provide de-emphasis for the receive audio and drives the audio amplifier on the System Board. The section of A202 with pins 8, 9, 10 provides a 2.7-volt reference to the audio processor and microphone circuits. The section of A202 with pins 5, 6, 7 provides shaping for the 9600 baud digital signal generated by modem IC A4. The section of A202 with pins 12, 13, 14 provides the final shaping of the transmit audio which then drives the TX RF section.

Voltage Regulator (A203 with Q205 and Q206)

Pass transistor Q205 and voltage regulator package A203 generates 5.4 volts for the audio processor. Transistor Q206 is used to limit the current to avoid break down.

Comparator A204

The section of comparator A204 with pins 1, 2, 3 is used as a limiter to square up the discriminator audio which is then fed to the modem IC. In trunk mode, when 9600 baud data is being received by the radio, the audio will appear on pin 1 or A204.

LCD Board

The LCD board is composed of the following items:

- LCD Drive IC (A1)
- LCD
- Backlighting Circuit (Q1, Q2, and CR1-CR6)

The LCD driver converts data from the microcomputer into a signal which can drive the LCD display. The LCD display is equipped with eight characters (14 segments each) and eight status displays. Microcomputer signals drive the LCD driver which turns the LCD on. Also, this board has a backlighting circuit which, upon receiving a signal from the microcomputer, is enabled when any of the control switches (VOL, PTT, etc.) are operated.

Keypad

There are three sets of key switches (keypads) on the System model of M-PD 16 PLUS. The keypads consist of flexible cable and rubber contacts, and each connect through cable to the microcomputer.

UDC Connector

The UIC connector (located on the side of the radio housing) allows various kinds of external equipment connections to be made. External equipment connecting signals are as follows:

- TX Data
- RX Data
- PTT
- EXT MIC
- RX Audio Out
- T/R
- Mute
- Disc Out
- +7.5 Volts Switch Out
- EMER
- UDC

The radio control microprocessor senses the value of voltage at the UDC line and switches the appropriate audio circuits to provide proper radio/accessory operation. The UDC voltage is set by two resistors within the UDC connector.

Battery Pack

Two battery packs, one with 800 mAh capacity and one with 1200 mAh capacity are available for use with the M-PD radio. Both batteries provide a nominal 7.5 Vdc output.

The positive (+) charging contact is diode protected to protect the battery pack from external short-circuits. An internal thermistor senses variations in battery pack temperature to automatically control a charger and provide a maximum charge without overheating the battery pack. Both battery packs can be charged in one hour.

The battery is shipped to the customer fully charged and ready for use. However, if the battery pack is stored for any length of time, it should be fully charged before placing into service.

Charger combinations for the battery packs are available with charge times of one hour, three hours, and 16 hours. A combination can be a single unit desk or a vehicular charger, or a wall-mounted multiple charger.

Charge Level

A fully charged battery pack should provide a terminal voltage of greater than 7.5 V. A fully discharged battery pack should provide a reading of no less than 6 V.

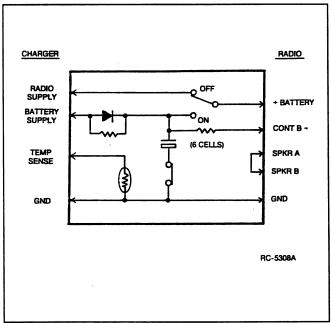


FIGURE 10 - BATTERY PACK

Battery Check

One of the best service checks for the rechargeable battery packs is easily obtained by measuring the milliampere-hour capacity. The results of the measurement can then be compared with the rated capacity of the battery pack to determine the general condition of the battery.

First, it is necessary to find the percentage of rated capacity. This is obtained by measuring the time it takes to discharge a fully charged battery pack until the terminal voltage drops to 6 V. The proper load resistor for each of the battery packs is shown in Table 1.

Then use the formula:

T/60 = %

Where T is the time in minutes required to discharge the battery pack to 6 volts and % is the percentage of rated capacity the battery delivered to a load. For example, assume the standard battery pack voltage dropped to 6 volts in 65 minutes. Using the formula:

65/60 = 108 (percent of capacity)

Now multiply the percentage of capacity by its rated capacity (see Table 1):

 $108 \times 800 \text{ mA} = 864 \text{ mAh}$

The 864 milliampere-hours is the actual capacity of the battery pack.

MAINTENANCE

This Maintenance section provides information on adjustments of the radio (transmit, receive, and synthesizer), preventive maintenance and a disassembly procedure. Information is also provided for removing and replacing chip components and module replacement. The Service Section, listed in the table of contents, provides a more complete set of alignment procedures for the radio plus a detailed troubleshooting procedure.

INITIAL ADJUSTMENT

The M-PD 16^{PLUS} radio personality is programmed using an IBM compatible personal computer and programming software. The procedure is described in the applicable programming manual.

After the radio personality has been programmed, the following adjustments should be made by a qualified electronics technician.

Transmit Circuit Alignment

The transmit circuit is factory tuned and should not require any readjustment. The frequency and modulation should be measured and recorded for future reference.

Receive Circuit

No initial adjustments to the receive circuit are required.

NOTE

As the voltage drops very fast near the end of the discharge cycle, be very careful to avoid discharging the battery pack below 6 volts.

TABLE 1 - CAPACITY MEASUREMENT DATA				
RECHARGEABLE BATTERY PACK	RATED CAPACITY	AVERAGE DISCHARGE (FOR 60 MINUTES)	LOAD RESISTOR (R & L)	END VOLTAGE
6 CELLS	800 MAH	800 MAH	9.375 OHMS 8 WATTS	6 VDC
6 CELLS	1200 MAH	1200 MAH	6.25 OHMS 12 WATTS	6 VDC

Synthesizer Circuit

No initial adjustments to the synthesizer are required.

PREVENTIVE MAINTENANCE

To ensure a high operating efficiency and to prevent mechanical and electrical failures, routine checks should be performed of all mechanical and electrical parts at regular intervals. Preventive maintenance should include the following checks.

Antenna

The antenna and antenna contact should be kept clean and free from dirt or corrosion. If the antenna or contact should become dirty or corroded, loss of radiation and a weak signal will result.

Mechanical Inspection

Since portable radio units are subject to shock and vibration, check, for loose plugs, nuts, screws and other parts to make sure that nothing is working loose.

Alignment

The transmit and receive circuit meter readings should be checked periodically and the alignment "touched up" when necessary. Refer to the applicable alignment procedure and troubleshooting sheet (found in the Service Section) for typical voltage readings.

Frequency Check

Check transmit frequency and deviation. Normally, these checks are made when the unit is first put into operation. They should be repeated after the first month of operation, then again one time each year.

DISASSEMBLY

Procedures to access the Radio board (transmit, receive, and synthesizer circuits) or Control Board for servicing are explained in the following paragraphs. Refer to Figure 11.

CAUTION

Always remove the battery pack before removing any component board to avoid blowing the fuse.

Equipment Required

- Small Phillips-head screwdriver
- Small flat-blade screwdriver
- Needle-nose pliers
- Allen-head wrench for removing set screws
- Pencil type soldering iron (25-40 watts)
 with a fine tip

NOTE

Screws are not captive. Be careful not to lose them.

Radio Board Access

- 1. Loosen, but do not remove, the four screws shown at [A] and [B] (Figure 12).
- 2. Carefully remove the back cover. For normal radio alignment, the back cover is all that needs to be removed. When tightening the captive screws, they should be no tighter than 4 +/- 0.5 inch-pounds.
- 3. Unscrew and remove the antenna at [C] and UDC RF connector at [D] (Figure 13).
- 4. Remove the six screws at [E] using the Phillips-head screwdriver. The radio portion can now be detached from the rear cover.
- 5. Remove the shield cover [F] from the eggcrate (Figure 14).

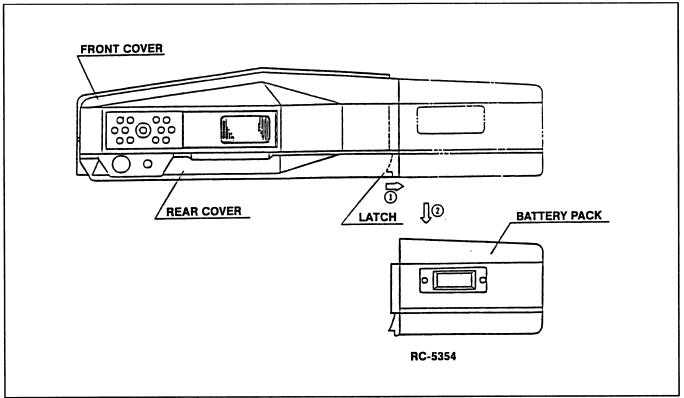


FIGURE 11 - DISASSEMBLY

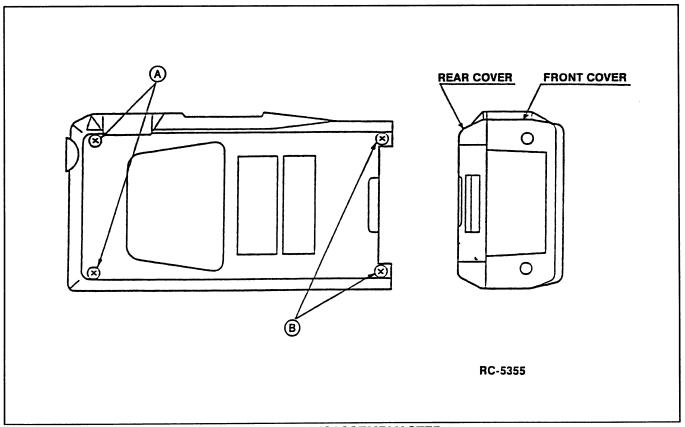


FIGURE 12 - DISASSEMBLY STEP 1

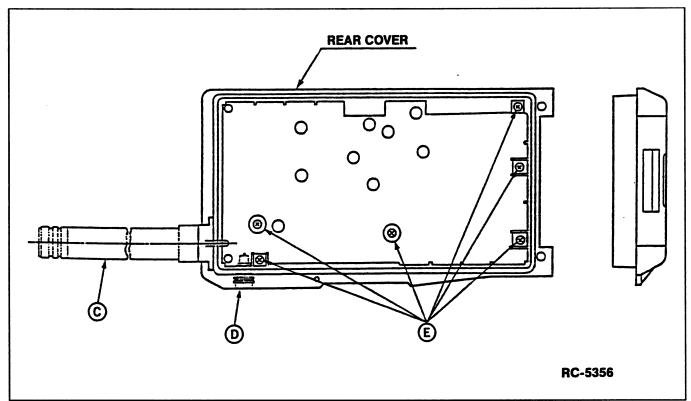


FIGURE 13 - DISASSEMBLY STEP 3

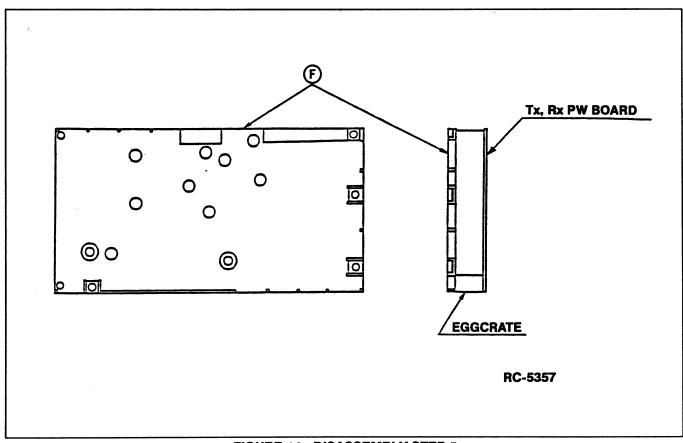


FIGURE 14 - DISASSEMBLY STEP 5

- 6. Remove the tap screw at [G] using the Phillipshead screwdriver (Figure 15).
- 7. Unsolder the antenna switch lead connection at [H]. The antenna switch assembly can now be removed by hand (see Figure 15).

Control/Logic Board Access

- 8. Remove the five screws at [I] from the System board using the Phillips-head screwdriver (Figure 16).
- 9. Unplug the LCD control flex circuit at [J] from the connector at [K] (Figure 17). The System Board can now be removed from the LCD board.
- 10. Pull the contact pins at [L]] out of the socket in the SPK/MIC flex circuit (Figure 18).
- 11. Remove the seven screws at [M] using the Phillips-head screwdriver. The LCD board can now be removed.

REPLACEMENT

The major components of the M-PD 16^{PLUS} Personal Radio are the PA, TX-AMP (driving amplifier), PC (Power Control Module), VCO (Voltage-Controlled Oscillator), and the VCTCXO (Reference Oscillator). These are very reliable devices and will not normally need to be replaced. Before replacing any of these modules, always check out the associated circuitry carefully.

To remove any of these major components, refer to the applicable replacement procedure found in the Service Section.

TROUBLESHOOTING PROCEDURE

Maintenance of the M-PD 16^{PLUS} Personal Radio is facilitated by using the Troubleshooting Procedures and service techniques unique to this radio. The Troubleshooting procedures are designed to quickly locate the defective component or circuit. These procedures are found in the Service Section.

WEATHERPROOF INTEGRITY

The M-PD 16^{PLUS} radio is designed to meet MIL-810-D specification for Blowing Rain. All access to the M-PD radio are protected from water entry by suitable gaskets and seals. However, degradation due to use, or disassembly during repairs, may affect the integrity of the seals as provided by factory assembly. A maintenance procedure is provided in the Service Section to assure that the radio housing will continue to meet the weatherproof features as designed.



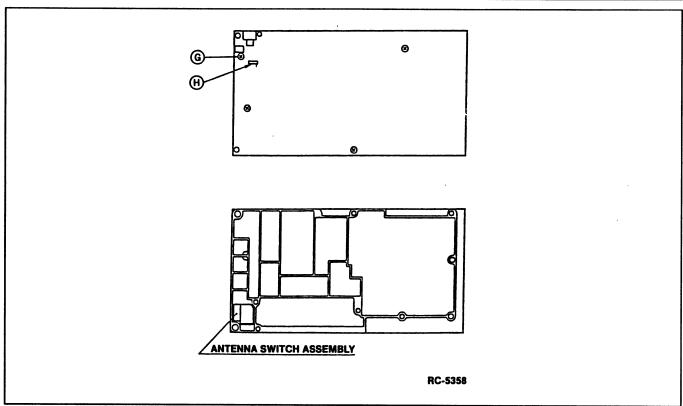


FIGURE 15 - DISASSEMBLY STEP 6

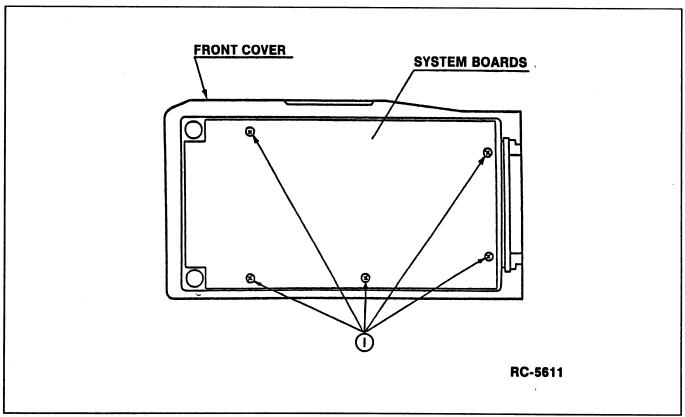


FIGURE 16 - DISASSEMBLY STEP 8

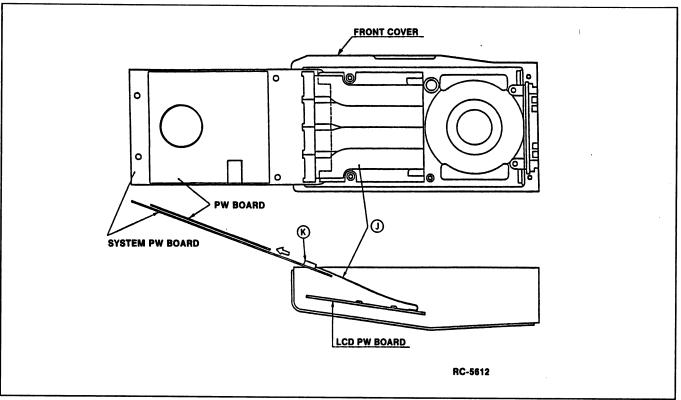


FIGURE 17 - DISASSEMBLY STEP 9

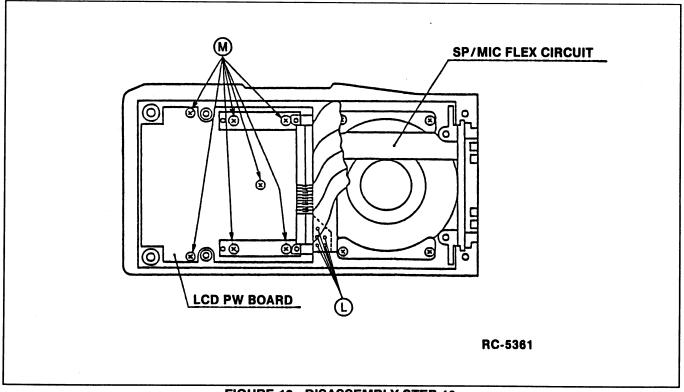
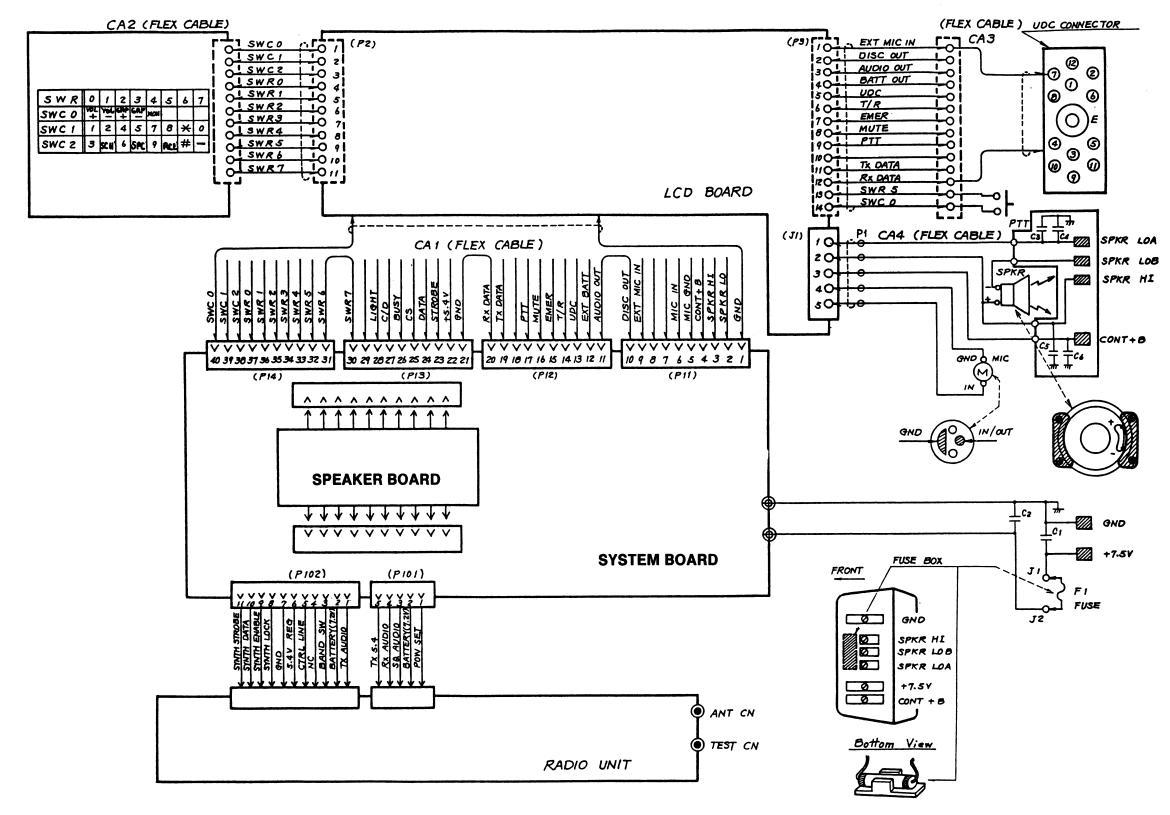


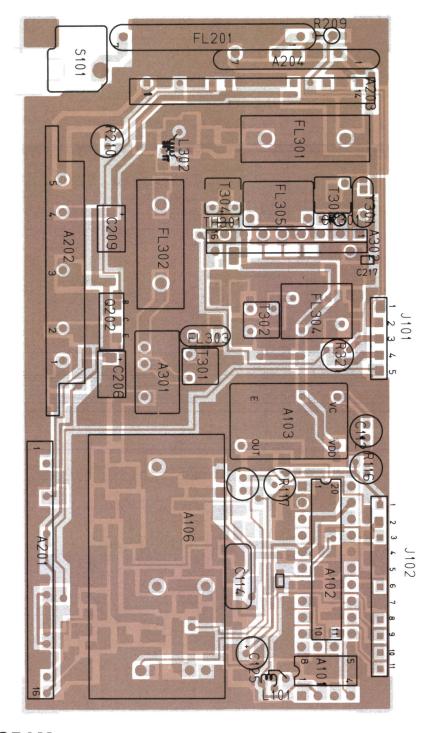
FIGURE 18 - DISASSEMBLY STEP 10



RC-5613

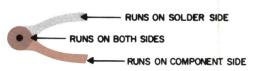
INTERCONNECTION DIAGRAM

COMPONENT SIDE

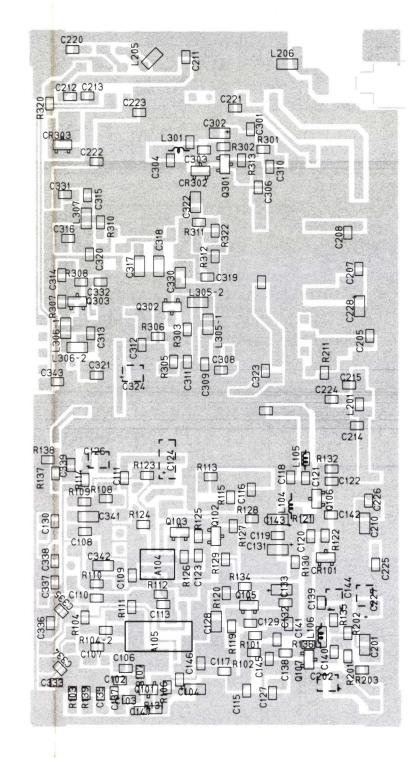


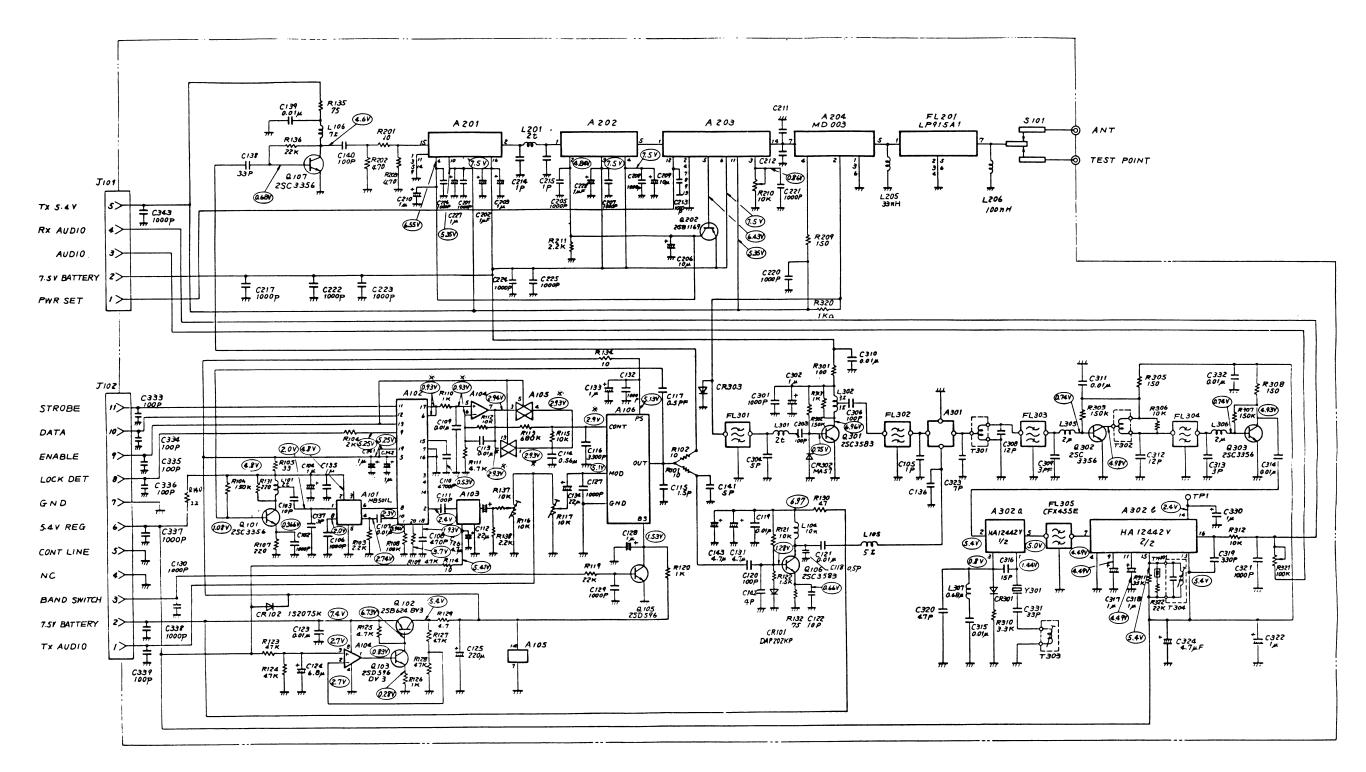
OUTLINE DIAGRAM

RADIO BOARD



SOLDER SIDE





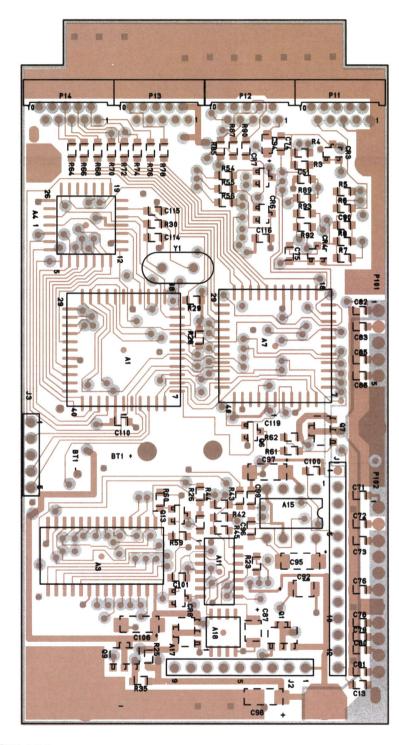
* ; TYPICAL VOLTAGE AT MIDDLE CHANNEL

SCHEMATIC DIAGRAM

RADIO BOARD WITH TYPICAL VOLTAGE

(A2WE03707, Rev. 0/870202)

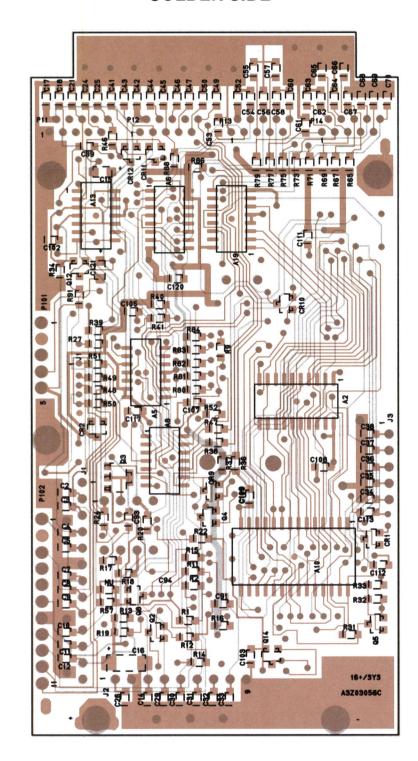
COMPONENT SIDE

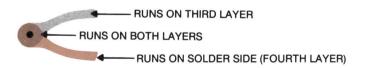


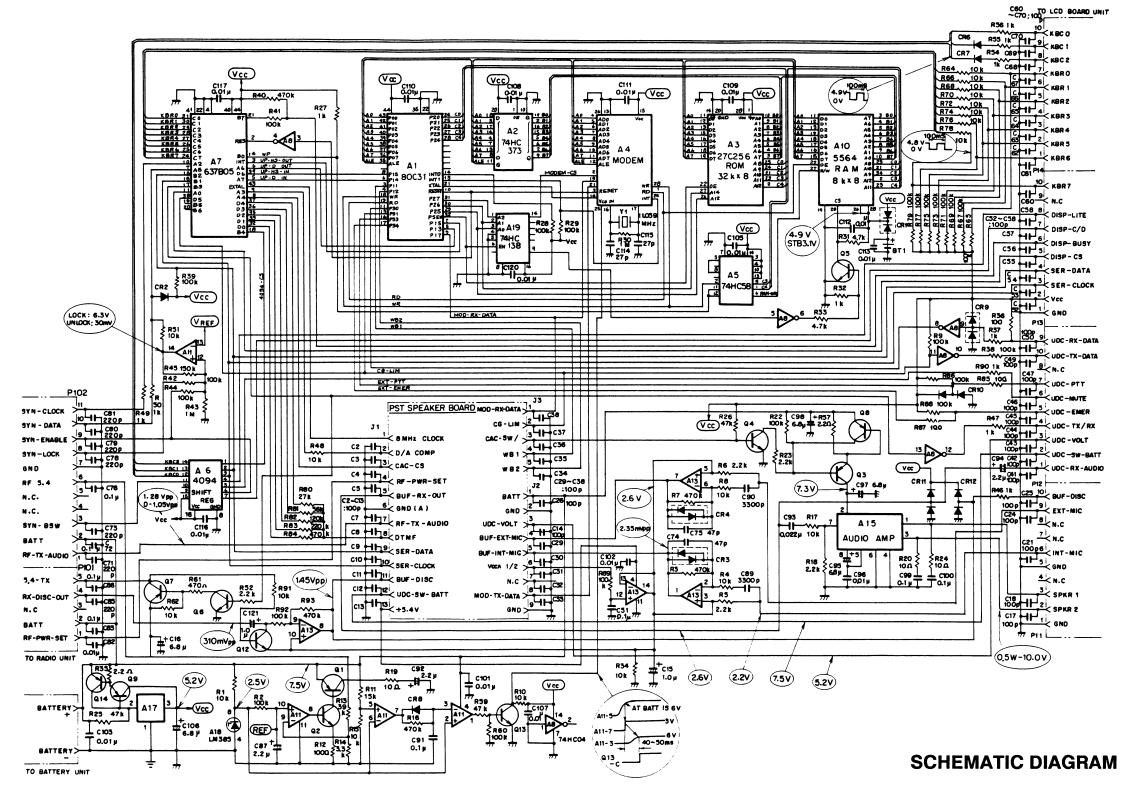
OUTLINE DIAGRAM

(A3Z03056C)

SOLDER SIDE



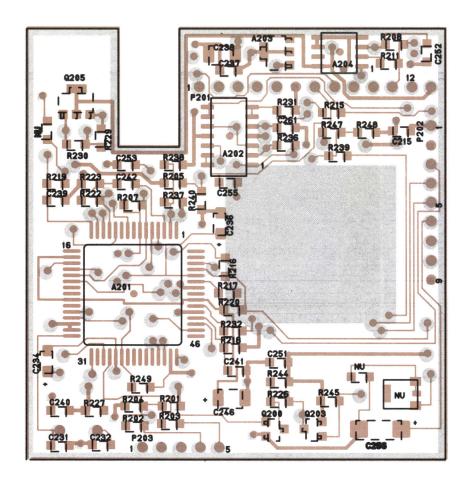




SYSTEM BOARD

(A3WE04350)

COMPONENT SIDE



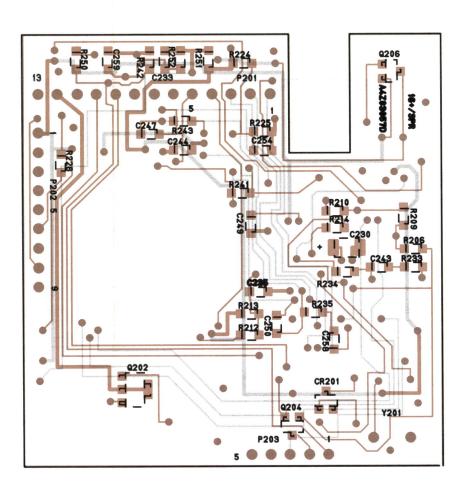


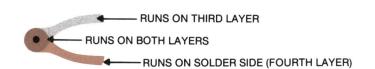
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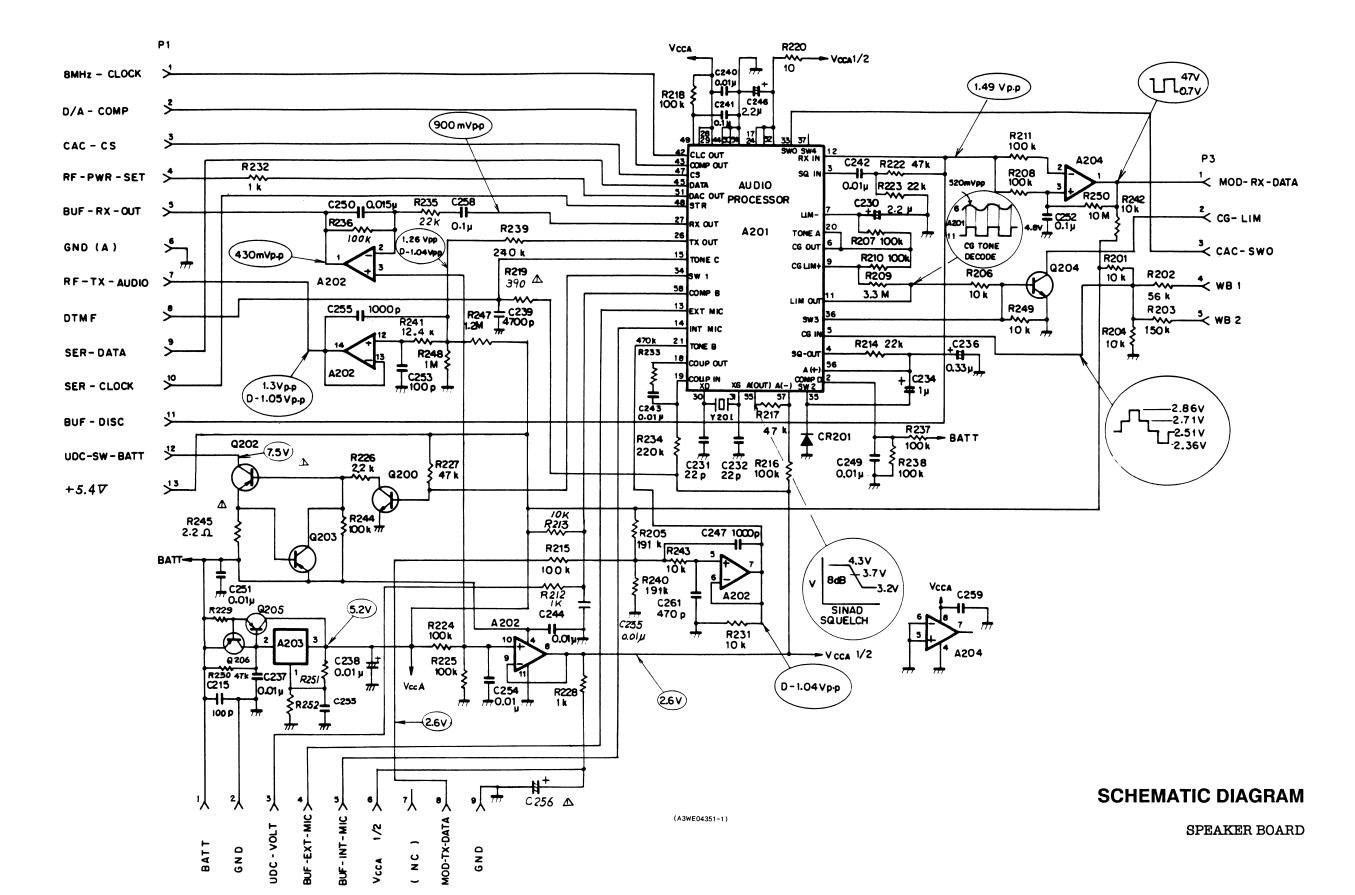
OUTLINE DIAGRAM

SPEAKER BOARD

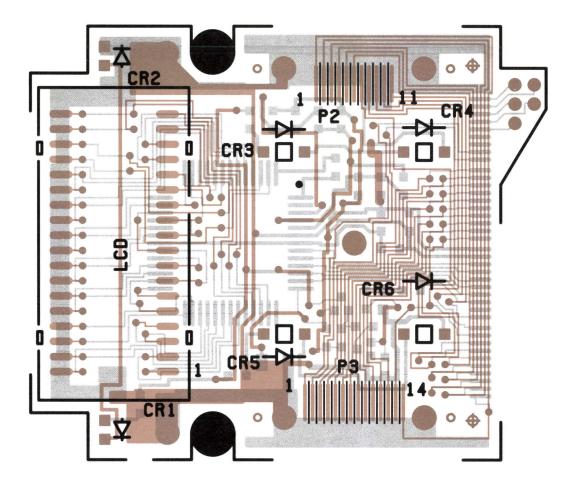
SOLDER SIDE



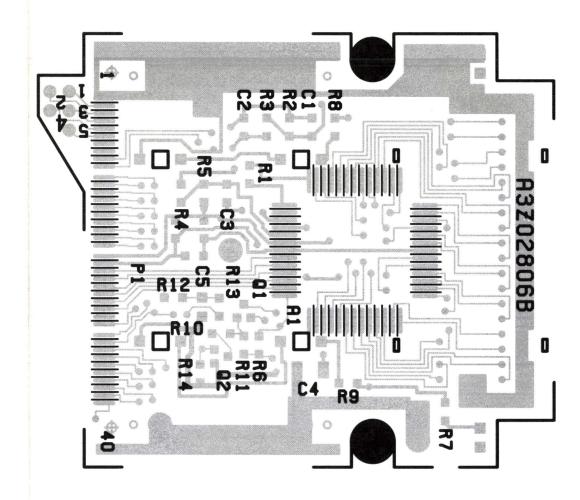




COMPONENT SIDE



SOLDER SIDE

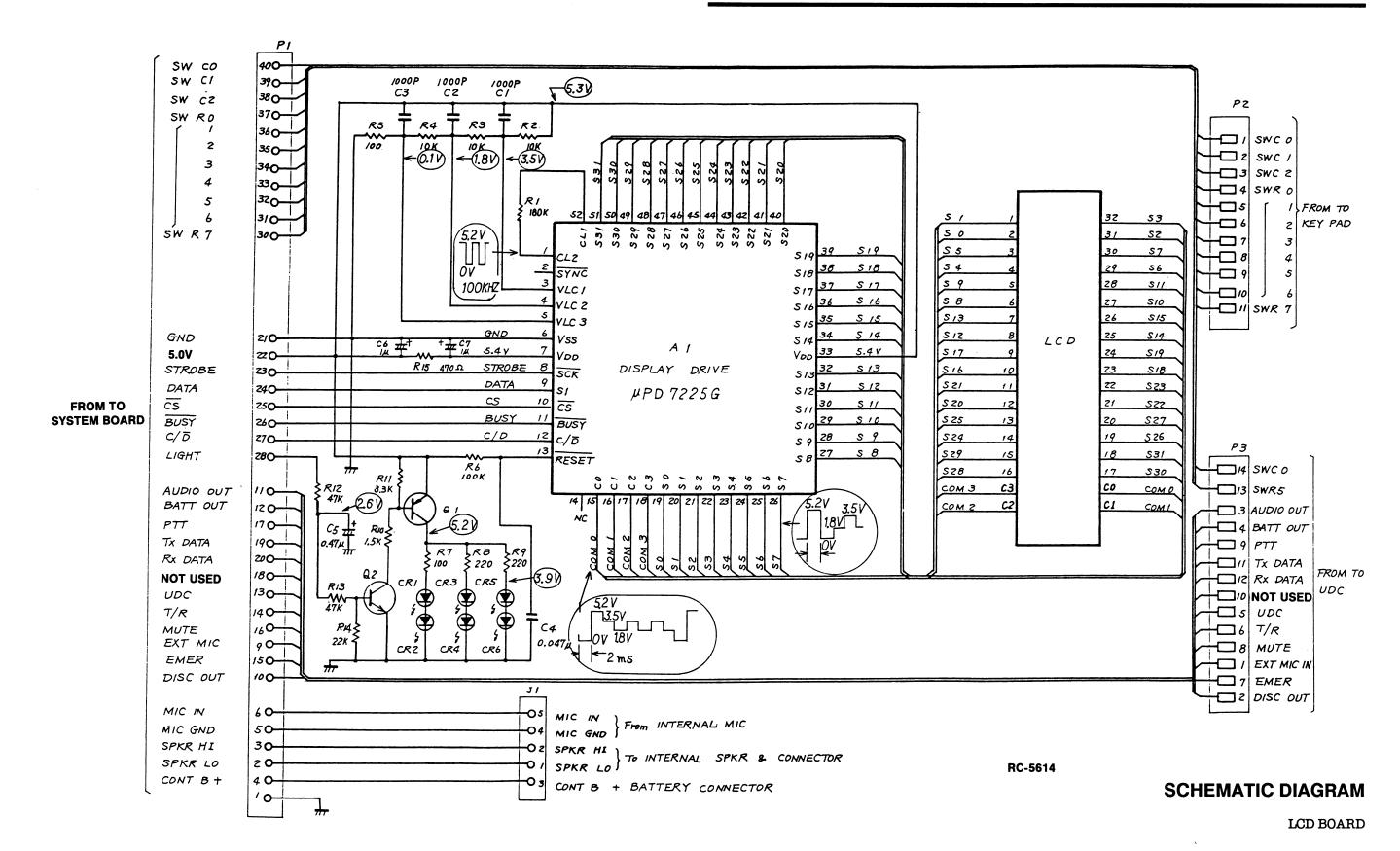


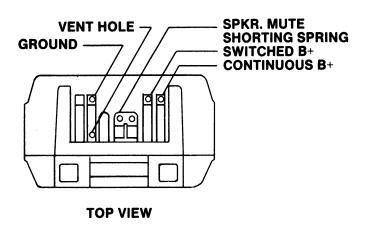
(A3Z02806B)

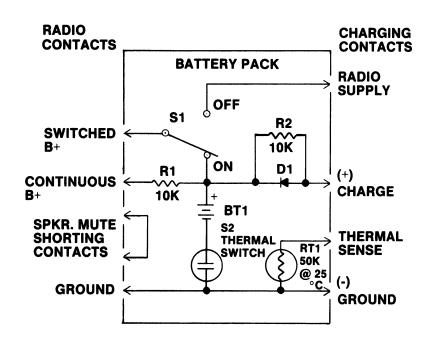
RUNS ON SOLDER SIDE RUNS ON BOTH SIDES RUNS ON COMPONENT SIDE

OUTLINE DIAGRAM

LCD BOARD

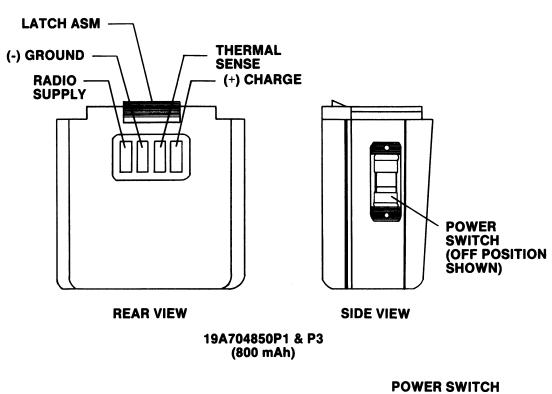


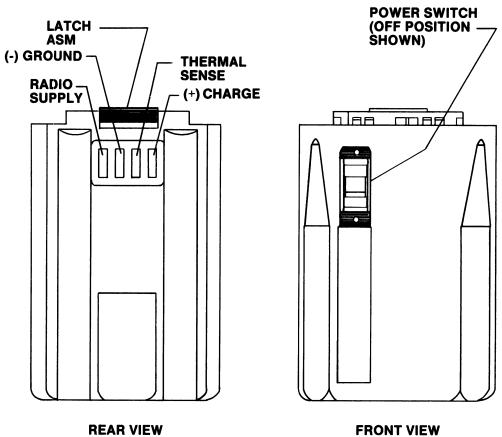




SCHEMATIC & OUTLINE DIAGRAM

800 mAh & 1200 mAh BATTERY PACKS

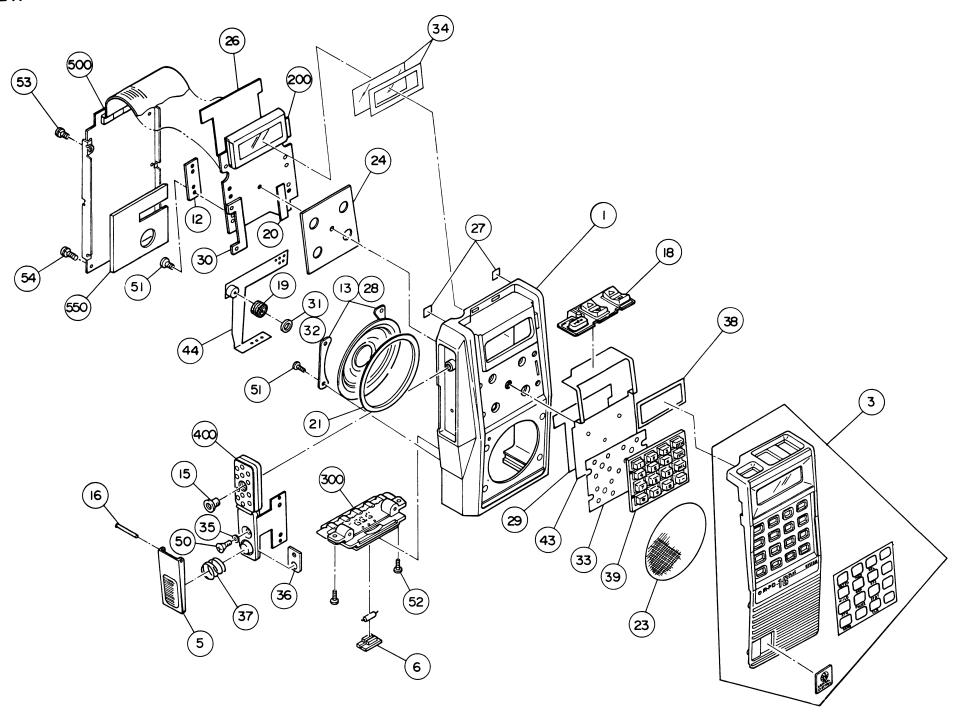




19A704860P1 & P3 (1200 mAh)

RC-5493

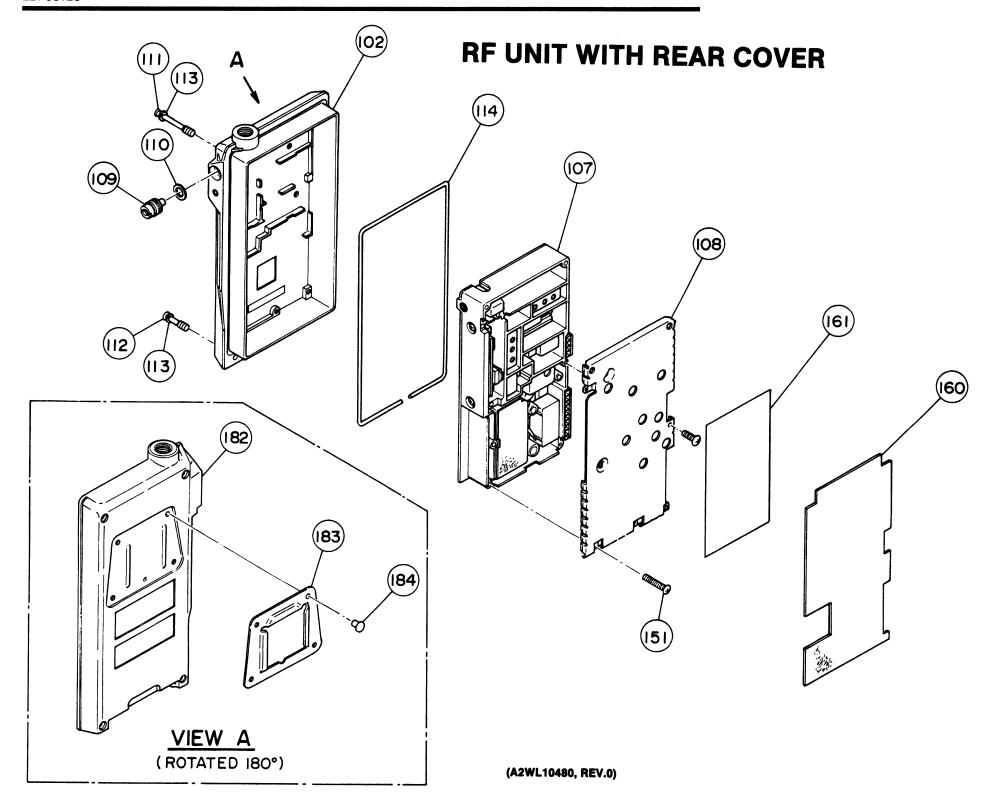
M-PD I6 PLUS FRONT ASSEMBLY SYSTEM TYPE EXPLODED VIEW



(A2WL10474)

ILLUSTRATED MECHANICAL PARTS BREAKDOWN

FRONT ASSEMBLY SHEET 1



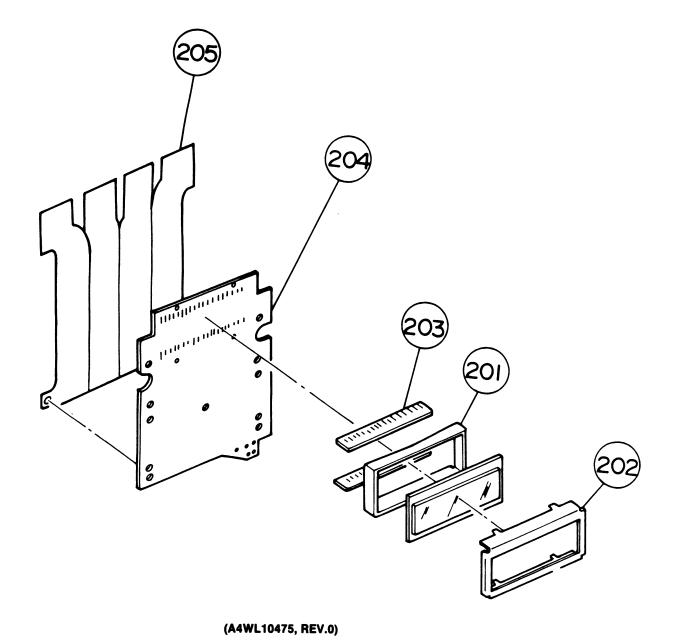
ILLUSTRATED MECHANICAL PARTS BREAKDOWN

RF UNIT WITH REAR COVER

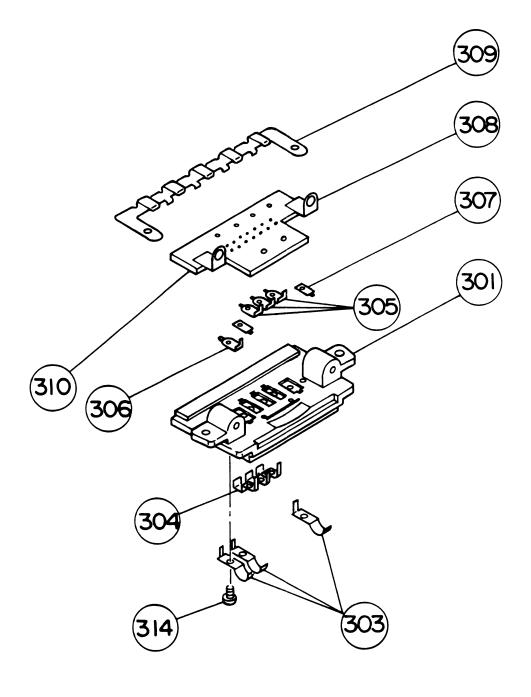
SHEET 2

LBI-38126

LCD BOARD SUB ASSEMBLY (PART NUMBER 200)



BASE PLATE SUB ASSEMBLY (PART NUMBER 300)

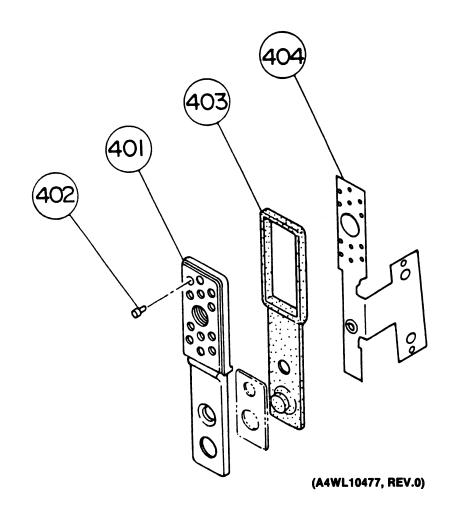


(A4WL10298, REV.0)

ILLUSTRATED MECHANICAL PARTS BREAKDOWN

SHEET 3

UDC PTT PLATE SUB ASSEMBLY (PART NUMBER 400)

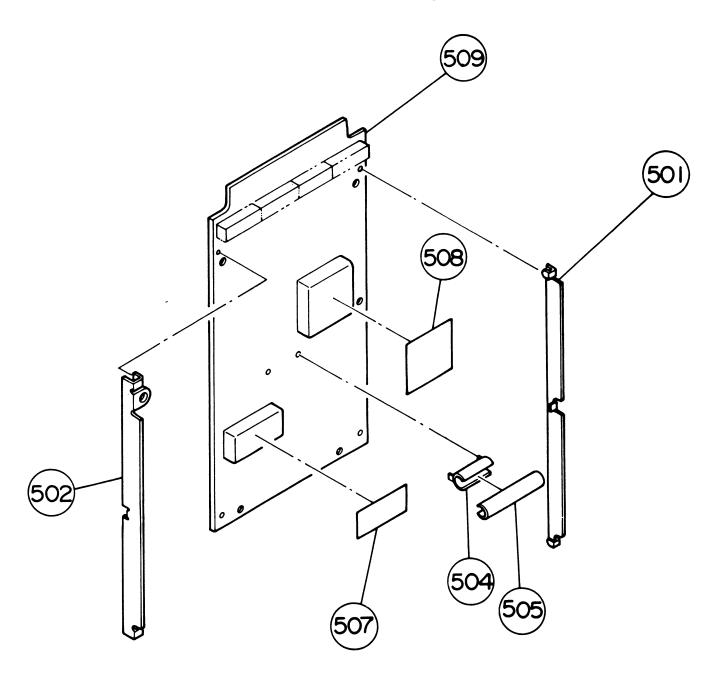


ILLUSTRATED MECHANICAL PARTS BREAKDOWN

SHEET 4

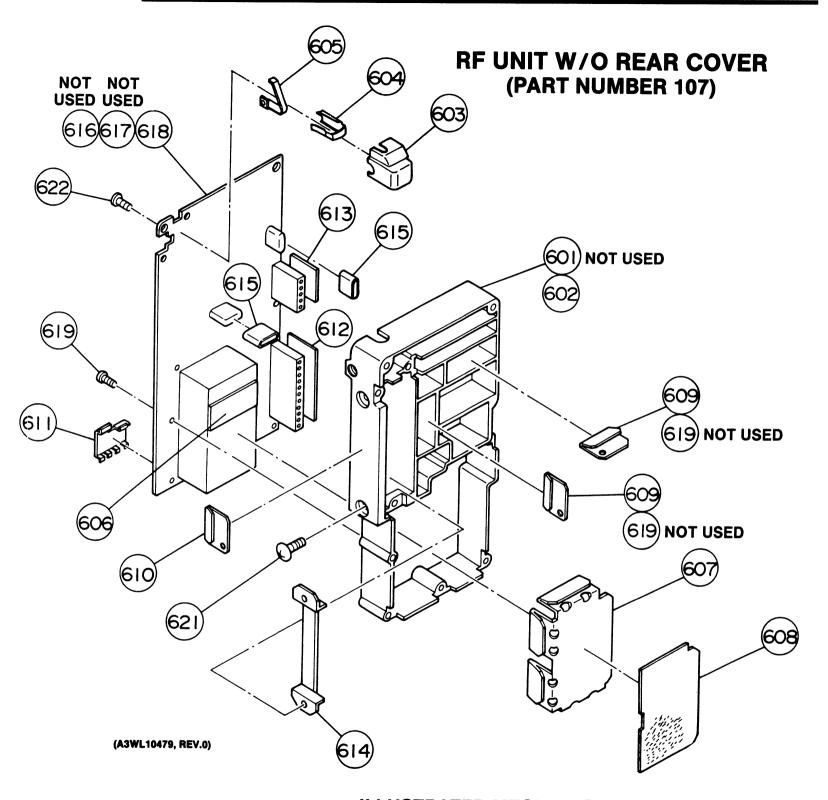
SYSTEM BOARD ASSEMBLY (PART NUMBER 500)

4 C 5 &



(A4WL10478, REV.0)

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ILLUSTRATED MECHANICAL PARTS BREAKDOWN

RF UNIT W/O REAR COVER (PART NUMBER 107) SHEET 5

PARTS LIST

LBI-31910B M-PD 16 PLUS FRONT ASSEMBLY K19/A4WE04129 (MECHANICAL PARTS)

SYMBOL	GE PART NO.	DESCRIPTION			
1	K19/AlWL09501	Front Cover (Al)			
2	1137 1111203301	NOT USED			
3	K19/A1WL09708	Front Escutcheon (STD), w/window (K19/A3WL07574)			
4		NOT USED			
5	K19/A3WL07575	PTT Lever			
6	K19/A3WL07577	Fuse Cover			
7		NOT USED			
thru 9					
10		NOT USED			
11		NOT USED			
12	K19/A4WL07892	Plate			
13	K19/A4WL07607	SPKR Mounting Bracket			
14		NOT USED			
15	K19/A4WL07605	UDC Nut			
16	K19/A4WL07434	Pivot Pin			
17		NOT USED			
18	K19/A3WL10436	Top Switch Pad			
19	K19/A4WL07594P2	MIC Gasket			
20	K19/A4WL07882	Elastic Rubber			
21	K19/A4WL07910	SPKR Gasket			
22		NOT USED			
23	K19/A4WL07435	SPKR Dust Screen			
24	K19/A4WL07606	Insulator (LCD BD)			
25		NOT USED			
26	K19/A4WL08445	LCD Sheet			
27	K19/A4WL07664	Insulator Sheet			
28	K19/A4WL08708	SPKR Mounting Rubber			
29	K19/A4WL08088	Adhesion Sheet			
30	K19/A4WL08409	Rubber Sheet			
31	K19/A4WL08385	MIC Film			
32	K19/A4WL09037				
33		Adhesion Ring NOT USED			
34	K19/A4WL08437	Window Sheet			
35	K19/A4WL08802	Nylon Washer			
36	K19/A4WL09662	PTT Spacer			
37	K19/A4WL09422	Coil Spring			
38	K19/A4WL08673	Window Gasket			
39	K19/A3WL10189	16 Button Keypad			
40		NOT USED			
41	K19/A3WL08438	STD Rubber Plate			
42		NOT USED			
43	K19/A3WL08836	Top Flex. Circuit (STD)			
44	K19/A3WL08835	SPKR/MIC Flex. Circuit			
45	,	NOT USED			
thru 49					
50	K19/A4WL08827P1	Flat Head Screw, M2.6x4			
51	K19/A4WL08828P2	Pan Head Tapping Screw, M2x6			
52	K19/A4WL08828P3	Pan Head Tapping Screw, M2x10			

SYMBOL	GE PART NO.	DESCRIPTION
53	K19/A4WL08827P4	Pan Head Screw with SW, M2x6
54	K19/A4WL08327P5	Pan Head Screw with SW, M2x8
55		NOT USED
		RF ASSEMBLY (800 MHZ) (MECHANICAL PARTS)
101		NOT USED
102	K19/A2WL10432	Rear Cover Sub Assembly. Consists of:
131		NOT USED
182	K19/A1WL09199	Rear Cover, Al
183	K19/A3WL07509	Receptacle Plate
184	K19/A4WL07694	Rivets
103 thru 106		NOT USED
107	K19/A4WE03902Pl1	RF UNIT W/O REAR COVER (800 MHz). SEE 600 SERIES NUMBERS
108	K19/42WL07512	TX/RX Shield Cover
109	K19/A4WL08826	RF Connector
110	K19/A4WL07880	RF Connector Gasket
111	K19/A4WL10041P1	Captive Screws (Stainless)
112	K19/A4WL10041P2	Captive Screws (Stainless)
113	K19/A4WL08802	Nylon Washer
114	K19/A4WL08383	Housing Gasket
150	W19 / N A 31 0 0 0 2 7 2 2	Dan Hoad Caray with Cla Mand
150	K19/A4wL08827P3	Pan Head Screw with SW, M2x4
151	K19/A4WL08827P6 K19/A4WL08828P1	Pan Head Screw with SW, M2x15
152 153	K19/A4WL08828P1	Pan Head Tapping Screw, M2x4 Pan Head Screw, M2.6x6
.,,	112/144E00020F5	THE OWN OCCUPY METUAU
160	K19/A3WL10190	Insulator
161	K19/A4WL10433	Tracking Data Label
162	K19/A4WL10353P2	FCC Label (for STD)
163		NOT USED
164		NOT USED
200		LCD BOARD K19/A4WE03737 (MECHANICAL PARTS)
201	K19/A3WL07601	Light Diffuser
202	K19/A3WL07614	LCD Frame
203	K19/A4WL07665	Zebra Contacts
204	K19/A3WL07895	LCD P.W. Board
205	K19/A3WL08833	LCD-Cont Flex. Circuit
300		BASE PLATS K19/A3WL08781 (MECHANICAL PARTS)
301	K19/A2WL07573	Base Plate
302		NOT USED
303	K19/A4WL07611	Battery Connector Springs
304	K19/A4WL07608	SPKR/MUTE Contacts
305	K19/A4WL07610	Contact Lug
306	K19/A4WL08007	Contact Lug B
307	K19/A4WL08629	Contact Lug C
308	K19/A4WL08630	Base Contact
309	K19/A4WL08628	Base Shield Spring
	K19/A3WL08672	Base P.W. Board
310		
310 311 thru		NOT USED

SYMBOL	GE PART NO.	E PART NO. DESCRIPTION			
314	K19/A4WL08827P2	Pan Head Screw			
315		NOT USED			
thru 317					
400		UDC PTT K19/A3WL10435 (MECHANICAL PARTS)			
401	K19/A3LW07576	UDC PTT Plate			
402	K19/A4LW07604	UDC Contacts			
403	K19/A3LW07580	PTT Switch Pad			
404	K19/A3LW08834	UDC PTT Flex. Circuit			
500		SYSTEM BOARD K19/A4WE04130 (MECHANICAL PARTS)			
501	K19/A3WL07295	B + Strap			
502	K19/A3WL07296	Ground Strap			
503	K19/A4WL08244	B + Strap Sheet			
504	K19/A4WL07514	Battery Holder			
505	K19/A4WL07863	LI-Battery Cover			
506	K19/A4WL07664	Insulator Sheet			
507	K19/A4WL10182	Yellow Label A			
508	K19/A4WL10431	Yellow Label B			
509	K19/A3WL09726	System Board			
550	K19/A4WE04131	Speaker Board Assembly			
551	K19/A3WL09728	Speaker Board			
107		RF UNIT W/O REAR COVER (800 MHz) K19/A4WE03902P11 (MECHANICAL PARTS)			
601		NOT USED			
602	K19/A1WL07570P1	Egg Crate			
603	K19/A3WL07654	Antenna Switch Housing			
604	K19/A4WL09765	AntennaSwitch Spring A			
605	K19/A4WL07655	Antenna Switch Spring B			
606	K19/A4WL07727	Shield Plate			
607	K19/A4WL07595	Shield Cover			
608	K19/A4WL08494	VCO Rubber			
609	K19/A4WL08829	RF Spring A			
610	K19/A4WL08830	RF Spring B			
611	K19/A4WL08832	RF Shield Plate			
612	K19/A4WL08495P1	Connector Spacer A			
613	K19/A4WL08495P2	Connector Spacer B			
614	K19/A4WL07663	Power Pack Bracket			
615	K19/A4WL05484	Crystal Protection Tube			
616		NOT USED			
617		NOT USED			
618	K19/A3WL08696	TX/RX P.W. Board			
619		NOT USED			
620	K19/A4WL08827P7	Pan Head Screw, M2x4			

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*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

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PARTS LIST

PARTS LIST

800 MHz M-PD PERSONAL RADIO A4WE03713 ISSUE 3

SYMBOL	GE PART NO.	DESCRIPTION
A101	K19/2AAH040019	Prescaler MB501LP
A102	K19/2AAJ004062	PLL MC145159P1
A103	K19/2YBA106090	VCTCXO A4WX01328-2.5 ppm
A104	K19/2AAB004243	OP AMP UPC1251BG
A105	K19/2ABC039105	Analog Switch UPD4066BG
A106	K19/200KLH3556	VCO A4WX01393 KLH3556
A201	K19/200KLH2591	Gain Hybrid KLH2591
A202	K19/2AAA013161	PA Pack A4WX01422-40
A203	K19/200KLH8515	PWR-Cont KLH8515
A204	K19/2AAH038047	MD003
A301	K19/5UAY001054	Mixer UST-3L A4WX01377
A302	K19/2AAJ008089	IF HA12442V
C102	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V
C103	K19/2CAK009257	Ceramic chip 10 pF ±0.5 pF 50V
C104	K19/2CCF004086	Tantalum 1 uF 16V
C105	K19/2CAK005669	Ceramic chip 1 pF ±0.25 pF 50V
2106	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V
107	K19/2CAK009216	Ceramic chip 0.01 uF ±10% 50V
C108	K19/2CAK009273	Ceramic chip 470 pF ±5% 50V
2109	K19/2CAK009216	Ceramic chip 0.01 uF ±10% 50V
2110	K19/2CAK009331	Ceramic chip 4700 pF ±10% 50V
2111	K19/2CAK009182	Ceramic chip 100 pF ±5% 50V
112	K19/2CBB034121	Electrolytic 22 uF 16V
1113	K19/2CAK009216	Ceramic chip 0.01 uF ±10% 50V
114	K19/2CDA055016	MET POLY-PROP Film 0.56 uF 50V
115	K19/2CAK009349	Ceramic chip 1.5 pf ±0.25 pF 50V
116	K19/2CAK009323	Ceramic chip 3300 pF ±10% 50V
2117	K19/2CAK009026	Ceramic chip 2 pF ±0.25 pF 50V
118	K19/2CAK009240	Ceramic chip 0.5 pF ±0.25 pF 50V
119	K19/2CAK009216	Ceramic chip 0.01 uF ±10% 50V
120 hru	K19/2CAK009257	Ceramic chip 10 pF ±0.5% 50V
122		
123	K19/2CAK009216	Ceramic chip 0.01 uF ±10% 50V
124	K19/2CCF006024	Tantalum 6.8 uF 10V
125	K19/2CBB062098	Electrolytic 220 uF 16V
126	K19/2CCF007022	Tantalum 4.7 uF 16V
127	K19/2CAK009208	Ceramic chip 1000 pF +10% 50V
128	K19/2CCF004086	Tantalum 1 uF '6V
129 nd	K19/2CAK0G9208	Ceramic chip 1000 pF ±10% 50V
130		
131	K19/2CCF007022	Tantalum 4.7 uF 16V
132	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V
133	K19/2CCF004086	Tantalum 1 uF 16V
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SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
C134	K19/2CBB034121	Electrolytic 22 uF 16V	C333 thru	K19/2CAK009182	Ceramic chip 100 pF ±5% 50V
C135	K19/2CCF004086	Tantalum 1 uF 16 V	thru C336	I	1
C137	K19/2CAK009034	Ceramic chip 3 pF ±0.25 pF 50V	C337 and	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V
C138	K19/2CAK009257	Ceramic chip 10 pF ±0.5% 50V	C338		1
C139 C140	K19/2CAK009216 K19/2CAK009257	Ceramic chip 10 pF +0 5% 50V	C339	K19/2CAK009182	Ceramic chip 100 pF ±5% 50V
C140 C141	K19/2CAK009257 K19/2CAK009059	Ceramic chip 10 pF +0.5% 50V Ceramic chip 5 pF +0.25 pF 50V	C341 and	K19/2CCF004086	Tantalum 1 uF 16V
C141 C142	K19/2CAK009059 K19/2CAK009042	Ceramic chip 5 pF ±0.25 pF 50V Ceramic chip 4 pF ±0.25 pF 50V	C342	100000000	
C142 C143	K19/2CAK009042 K19/2CCF007022	Ceramic chip 4 pF ±0.25 pF 50V Tantalum 4.7 uF 16V	C343	K19/2CAD009208	Ceramic chip 1000 pF ±10% 50V
C201	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V	11 '	1	DIODES
C202	K19/2CCF004086	Tantalum 1 uF 16V	CR101	K19/2QBE005024	DAP202KP
and C203	1		CR102	K19/2QBA006166	182075K
C205	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V	CR301	K19/2QBA006166	182075K
C206	K19/2CCB026018	Tantalum 10 uF 16V	CR302	K19/2ABA012024	MA57
C207	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V	CR303	K19/2QBA005135	1SV128-A
and C208	1	1	()	1	
C209	K19/2CCB026018	Tantalum 10 uF 16V	FL201	K19/2FBB002117	LP915A1A
C210	K19/2CCF004086	Tantalum 1 uF 16V	FL301	K19/2FBD002117	A4FX01849-1
C211	K19/2CAK009026	Ceramic chip 2 pF ±0.25 pF 50V	and FL302	, Kis,	ATIANIOTO I
and C212	1	1	FL302	K19/2FAA103066	A4WX01612
C213	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V	FL303	K19/2FAA103000	A4WX01613
C214 and	K19/2CAK005669	Ceramic chip 1 pF ±0.25 pF 50V	FL305	K19/2FAD001242	CPX455E
and C215	1	1	$(\cdot \cdot \cdot \cdot \cdot \cdot \cdot \cdot \cdot $	1 "	
C217	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V	(1	
C220 thru	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V	J101	K19/2PDA023036	69775-005
C226	1 '	1	J102	K19/2PDA023044	69775-011
C227 and	K19/2CCF004086	Tantalum 1 uF 16V	I = I	1	
C228	1	1	L101	K19/2EDE001022	A4WX01365
C301	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V	L104	K19/2LAD001088	NL322522T-010M
C302	K19/2CCF004086	Tantalum 1 uF 16V	L105	K19/2LAB024140	A4FX01878 #5
C303	K19/2CAK009182	Ceramic chip 100 pF ±5% 50V	L106	K19/2LABC24165	A4FX01878 #7
C304	K19/2CAK009059	Ceramic chip 5 pF ±0.25 pF 50V	L201	K19/2LAB024116	A4FX01878 #2
C306	K19/2CAK009182	Ceramic chip 100 pF ±5% 50V	L205	K19/2LAD001104	NL322522T-033M
C308	K19/2CAK009109	Ceramic chip 12 pF ±5% 50V	L206	K19/2LAD001070	NL322522T-R10M
C309	K19/2CAK009034	Ceramic chip 3 pF ±0.25 pF 50V	L301	K19/2LAB024116	A4FX01878 #2
(° (°) and	K19/2CAK009216	Ceramic chip 0.01 uF ±10% 50V	L302	K19/2EDE001030	A4WX01426
C31:	()	()	L305 and	K19/2LAD001062	MLF3216D1ROK
Cata	K19/2CAK009109	Ceramic chip 12 pF ±5% 50V	L306	1	1
C31.3	K19/2CAK009034	Ceramic chip 3 pF ±0.25 pF 50V	L307	K19/2LAD001021	MLF3216DR68K
C314 and	K19/2CAK009216	Ceramic chip 0.01 uF ±10% 50V	$i \downarrow j$	1	
C31 5	(<u></u>)	()	Q101	K19/2QAD004020	28C3356R22
C304	K19/2CAK009125	Ceramic chip 15 pF ±5% 50V	Q101	K19/2QAD004020 K19/2QAD004087	2SC3356R22 2SB624BV3
C.CLT and	K19/2CCF004086	Tantalum 1 uf 16V	Q102 Q103	K19/2QAD004087	2886248V3 28D596DV3
C318	ı J	()	Q105	K19/2QAD004046 K19/2QAD004046	2SD596DV3
C51 (K19/2CAK009190	Ceramic chip 330 pF ±5% 50V	Q105 Q106	K19/2QAD004049	2803583R32
C324	K19/2CAK009166	Ceramic chip 47 pF ±5% 50V	Q106	K19/2QAD004079	28C3356R22
C321	K19/2CAK009208	Ceramic chip 1000 pF ±10% 50V	Q202	K19/2QAB004020	28C3356R22 28B1169
C322	K19/2CCF004086	Tantalum 1 uP 16V	Q301	K19/2QAD004079	2SC3583R32
C323	K19/2CAK009299	Ceramic chip 7 pF ±0.5% 50V	9302	K19/2QAD004079	28C3356R22
C324 C329	K19/2CCF007022	Tantalum 4.7 uF 16V	and Q303	1	2003333,22
C329 C330	K19/2CAK009208 K19/2CCF004086	Ceramic chip 1000 pF +10% 50V	. []	()	1
C330	K19/2CCF004086 K19/2CAK009158	Tantalum 1 uF 16V Ceramic chip 33 pF +5% 50V	1 .)	1	
C331	K19/2CAK009158 K19/2CAK009216	Ceramic chip 33 pF ±5% 50V	R101 and	K19/2RGC003326	Square chip 1/16W 10 ohms ±5%
C332	K19/2CAKOU9210	Ceramic chip 0.01 uF ±10% 50V	R102	1	1
I	ı J	ı J	R103	K19/2RGC003136	Square chip 1/16W 2.2K ohms ±5%
J	ı J		. 1	()	l
	ı J	ı J	. 1	<i>i</i> , , , , , , , , , , , , , , , , , , ,	1
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1	ı J		.1)	, J	1

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

PARTS LIST

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
R104	K19/2RGC003110	Square chip 1/16W lK ohms ±5%			
R106	K19/2RGC003243	Square chip 1/16W 150K ohms ±5%	T301	K19/2LAB014893	A4#X01333
R107	K19/2RGC003060	Square chip 1/16W 22O ohms +5%	and T302	·	
R108	K19/2RGC003227	Square chip 1/16W 100K ohms ±5%	Т303	K19/2LAB014901	A4WX01334
R109	K19/2RGC003219	Square chip 1/16W 47K ohms ±5%	T304	K19/2LAB014919	A4WX01335
R110 R111	K19/2RGC003110 K19/2RGC003151	Square chip 1/16W 1K ohms +5%			
R111	K19/2RGC003131	Square chip 1/16W 4.7K ohms ±5% Square chip 1/16W 10K ohms ±5%	8101	K19/2A3WL07654	Antenna Switch.
R113	K19/2RGC003284	Square chip 1/16W 680K ohms ±5%	"""	, 2204201004	Autous Office.
R114	K19/2RGC003326	Square chip 1/16W 10 ohms ±5%			
R115	K19/2RGC003177	Square chip 1/16W 10K ohms ±5%	TH301	K19/2ABD016139	NTCD83018-3HG103HC
R116 and R117	K19/2RFB003253	Variable GF04W 10K ohms	¥301	K19/2YAA181657	
R119	K19/2RGC003193	Square chip 1/16W 22K ohms ±5%			
R120	K19/2RGC003110	Square chip 1/16W 1K ohms +5%			
R121	K19/2RGC003177	Square chip 1/16W 10K ohms ±5%	1		
R122	K19/2RGC003425	Square chip 1/16W 1.5K ohms ±5%			
R123 and R124	K19/2RGC003219	Square chip 1/16W 47K ohms ±5%			
R125	K19/2RGC003151	Square chip 1/16W 4.7K ohms ±5%			
R126	K19/2RGC003110	Square chip 1/16W 1K ohms ±5%			
R127 and R128	K19/2RGC003219	Square chip 1/16W 47K ohms ±5%			
R129	K19/2RGC003383	Square chip 1/16W 4.7 ohms ±5%			
R130	K19/2RGC003342	Square chip 1/16W 47 ohms ±5%			
R131	K19/2RGC003060	Square chip 1/16W 22O ohms ±5%	-		
R132	K19/2RGC003359	Square chip 1/16W 75 ohms ±5%			
R134	K19/2RGC003326	Square chip 1/16W 10 ohms ±5%			
R135	K19/2RGC003359	Square chip 1/16W 75 ohms ±5%			
R136	K19/2RGC003193	Square chip 1/16W 22K ohms ±5%			
R137	K19/2RGC003177	Square chip 1/16W 10K ohms ±5%			
R138 R140	K19/2RGC003136 K19/2RGC003334	Square chip 1/16W 2.2K ohms ±5%			
R201	K19/2RGC003334	Square chip 1/16W 22 ohms ±5% Square chip 1/16W 10 ohms ±5%			
R202 and R203	K19/2RGC003094	Square chip 1/16W 470 ohms ±5%			
R209	K19/2RAA001861	RD25S 1/4W 150 ohms ±5%			
R210	K19/2RFB003253	Variable GPO4W 10K ohms			
R211	K19/2RGC003136	Square chip 1/16W 2.2K ohms ±5%			
R301	K19/2RGC003037	Square chip 1/16W 100 ohms ±5%			
R302 and R303	K19/2RGC003243	Square chip 1/16W 150K ohms ±5%			
R305	K19/2RGC003045	Square chip 1/16W 150 ohms ±5%			
R306	K19/2RGC003177	Square chip 1/16W 10K ohms ±5%			
R307	K19/2RGC003243	Square chip 1/16W 150K ohms ±5%			
R308	K19/2RGC003045	Square chip 1/16W 150 ohms ±5%			
R310	K19/2RGC003144	Square chip 1/16W 3.3K ohms ±5%			
R311	K19/2RGC003201	Square chip 1/16W 33K ohms ±5%			
R312	K19/2RGC003177	Square chip 1/16W 10K ohms +5%			
R313 R320	K19/2RGC003110 K19/2RGC003110	Square chip 1/16W 1K ohms ±5% Square chip 1/16W 1K ohms ±5%			
R321	K19/2RGC003110 K19/2RPB003261	Variable GP04W 100K ohms			
R322	K19/2RGC003193	Square chip 1/16W 22K ohms ±5%			
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PARTS LIST

LBI-31908 M-PD 16 PLUS SYSTEM BOARD

SYMBOL	GE PART NO.	DESCRIPTION
		INTEGRATED CIRCUITS
A1	K19/2ADA015145	Micro Processor, MSM80C31FJS
A2	K19/2ABD025269	CMOS, uPD74HC373G-T1
A3	K19/2ACA055036	P-ROM, HN27C256PP-25
A4	19A704727P2	MODEM IC, 28 pin "J HOOK"
A5	K19/2ABD034014	CMOS, NJU74HC58M
A6	K19/2ABD025335	CMOS, uPD74HC4094G-T1
A7		PROM, HD637B05VOCP
A8	K19/2ABD025012	CMOS, uPD74HC04G-T1
A9		NOT USED
A10	K19/2ACA041358	RAM, TC5564APL-15
A11	K19/2AAB004284	OP Amp, uPC451G2-T1
A12		NOT USED
A13	K19/2AAB004284	OP Amp, uPC451G2-T1
A14		NOT USED
A15	K19/2AAJ010036	Audio IC, NJM2073D
A16	K19/2AAE053023	NOT USED Voltage Regulators, S-81250HG-RD-T1
A18	K19/2AAE053023	VTG-REP, LM385M-2.5
A19	K19/2ABD025327	CMOS, uPD74HC138G-T1
AIS	K19/2MBD023327	CHOS, UPD/ANCISOU-II
BT1	K19/5PBA004058	BR425, Lithium
C1		NOT USED
C2	K19/2CAK005909	Ceramic chip: 100 pF, 50V
thru C14		
C15	K19/2CCF002072	Tantalum: 1 uP, 10V
C16	K19/2CCF006024	Tantalum: 6.8 uF, 10V
C17	K19/2CAK005909	Ceramic chip: 100 pF, 50V
and C18		
C19 and		NOT USED
C20		
C21	K19/2CAK005909	Ceramic chip: 100 pF, 50V
C22 and		NOT USED
C23	İ	
C24 thru	K19/2CAK005909	Ceramic chip: 100 pP, 50V
C26		
C27 and		NOT USED
C28		
C29 thru	K19/2CAK005909	Ceramic chip: 100 pF, 50V
C38		
C39 and		NOT USED
C40		
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SYMBOL	GE PART NO.	DESCRIPTION
C41 thru C47	K19/2CAK005909	Ceramic chip: 100 pF, 50V
C48		NOT USED
C49 and C50	K19/2CAK005909	Ceramic chip: 100 pF, 50V
C51	K19/2CAK013010	Ceramic chip: 0.1 uF, 50V
C52 thru C58	K19/2CAK005909	Ceramic chip: 100 pF, 50V
C59		NOT USED
C60 thru C70	K19/2CAK005909	Ceramic chip: 100 pF, 50V
C71	K19/2CAK005917	Ceramic chip: 220 pF, 50V
C72	K19/2CAK013010	Ceramic chip: 0.1 uF, 25V
C73	K19/2CAK005917	Ceramic chip: 220 pF, 50V
C74 and C75	K19/2CAK005867	Ceramic chip: 47 pF, 50V
C76 C77	K19/2CAK013010	Ceramic chip: 0.1 uF, 25V NOT USED
C78 thru C81	K19/2CAK005917	Ceramic chip: 220 pF, 50V
C82	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
C83	K19/2CAK013010	Ceramic chip: 0.1 uF, 25V
C84		NOT USED
C85	K19/2CAK005917	Ceramic chip: 220 pF, 50V
C86	K19/2CAK013010	Ceramic chip: 0.1 uF, 25V
C87	K19/2CCF0U2080	Tantalum: 2.2 uF, 16V
C88 C89 and C90	K19/2CAK013143	NOT USED Ceramic chip: 3300 pF, 50V
C91	K19/2CAK013010	Ceramic chip: 0.1 uF, 50V
C92	K19/2CCF002080	Tantalum: 2.2 uF, 16V
C93	K19/2CAK013341	Ceramic chip: 0.022 uF, 50V
C94	K19/2CCF002080	Tantalum: 2.2 uF, 16V
C95	K19/2CCF006024	Tantalum: 6.8 uF, 10V
C96	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
C97 and C98	K19/2CCF006024	Ceramic chip: 6.8 uF, 10V
C99 and C100	K19/2CAK013010	Ceramic chip: 0.1 uP, 25V
C101 thru C103	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
C104		NOT USED
C105	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
C106	K19/2CCF006024	Tantalum: 6.8 uF, 10V
C107 thru C113	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
C114 and C115	K19/2CAK005834	Ceramic chip: 27 pF, 50V
C116 and C117	K19/2CAK013119	Ceramic chip: 0.01 uP, 50V
C118		NOT USED
C119	K19/2CAK005933	Ceramic chip: 470 pF, 50V
C120	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
C121	K19/2CCF002072	Ceramic chip: 1 uF, 16V

LBI-38126

PARTS LIST

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
	l	DIODES	R17	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ	R71	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
CR1	K19/2QBE005016	DAN202KT-96	R18	K19/2RGC001593	Square chip: 1/10W, 2.2 KohmJ	R72	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
and CR2			R19 and	K19/2RGC001502	Square chip: 1/10W, 10 ohmJ	R73	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
CR3	K19/2QBE005032	DA204KT-96	R20		İ	R74	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
and CR4			R21		NOT USED	R75	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
CR5		NOT USED	R22	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ	R76	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
CR6 thru	K19/2QBE005016	DAN202KT-96	R23	K19/2RGC001593	Square chip: 1/10W, 2.2 KohmJ	R77	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
CR8	ł		R24 R25	K19/2RGC001502 K19/2RGC001726	Square chip: 1/10W, 10 ohmJ Square chip: 1/10W, 47 KohmJ	R78 R79	K19/2RGC001627 K19/2RGC001643	Square chip: 1/10W, 10 KohmJ
CR9 thru	K19/2QBE005032	DA 204KT-96	and R26	K15/2RGC001/20	Square chip. 1/10w, 4/ Kommo	RBO	K19/2RGC001916	Square chip: 1/10W, 100 KohmJ
CR12			R27	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ	R81	K19/2RGC004035	Square chip: 1/10W, 27 KohmJ Square chip: 1/10W, 56 KohmJ
			R28	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ	R82	K19/2RGC004621	Square chip: 1/10W, 120 KohmF
J1	K19/	SL-113-T-11	and R29			R83	K19/2RGC001825	Square chip: 1/10W, 220 KohmJ
J2	K19/	SL-109-T-11	R30	K19/2RGC001775	Square chip: 1/10W, 1 MohmJ	R84	K19/2RGC001759	Square chip: 1/10W, 470 KohmJ
J3	K19/	SL-105-11	R31	K19/2RGC001619	Square chip: 1/10W, 4.7 KohmJ	R85	K19/2RGC001528	Square chip: 1/10W, 100 ohmJ
			R32	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ	R86	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
			R33	K19/2RGC001619	Square chip: 1/10W, 4.7 KohmJ	R87	K19/2RGC001528	Square chip: 1/10W, 100 ohmJ
P11 thru	K19/2PDA018085	10FM-STG	R34	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ	R88	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
P14		l I	R35	K19/2RGC001833	Square chip: 1/10W, 2.2 ohmK	and R89		. , ,
P101 P102	K19/2PDA023093 K19/2PDA023101	65646-205	R36	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ	R90	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ
P102	K19/2PDA023101	65646-211	R37	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ	R91	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
		TRANSISTORS	R38	K19/2RGC001528	Square chip: 1/10W, 100 ohmJ	R92		
Q1	K19/2QAD004103	2SB798T1DL	R39	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ	R93	K19/2RGC001759	Square chip: 1/10W, 470 KohmJ
Q2	K19/2QAD001034	2SC2462LCTL	R40	K19/2RGC001759	Square chip: 1/10W, 470 KohmJ	1		
Q3	K19/2QAD004103	2SB798T1DL	R41	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ	l		
Q4	K19/2QAD001034	2SC2462LCTL	and R42			XY1	K19/2YYZ001062	NB-0252-0.5t
Q5	K19/2QAD001133	2SC2620QCTL	R43	K19/2RGC001775	Square chip: 1/10W, 1 MohmJ			
Q6	K19/2QAD001034	2SC2462LCTL	R44	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ	¥1	K19/2YAA181756	11.0592 MHz, A4WX01730
Q7	K19/2QAD004103	2SB798T1DL	R45	K19/2RGC004449	Square chip: 1/10W, 150 KohmJ			
Q8 and Q9	K19/2QAD001026	2SA1121SBTL	R46 and R47	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ			
Q10		NOT USED	R48	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ			
Q11	K19/2QAD001026	2SA1121SBTL	R49 and	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ	ı		
Q12 and Q13	K19/2QAD001034	2SC2462LCTL	R50	K19/2RGC001627	Samuel Marie and Marie			
Q14	K19/2QAD001026	2SA1121SBTL	R52	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ	1		
,	,-,		R53	K19/2RGC001393	Square chip: 1/10W, 2.2 KohmJ NOT USED			
			R54	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ			
R1	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ	thru R56	,	Square entp. 1/104, 1 Roman	1		
R2	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ	R57	K19/2RGC001833	Square chip: 1/10W, 2.2 ohmK			
R3	K19/2RGC001759	Square chip: 1/10W, 470 KohmJ	R58	,	NOT USED			
R4	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ	R59	K19/2RGC001726	Square chip: 1/10W, 47 KohmJ			
R5 and	K19/2RGC001593	Square chip: 1/10W, 2.2 KohmJ	R60	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ			
R7	K19/2RGC001759		R61	K19/2RGC001569	Square chip: 1/10W, 470 ohmJ			
R8	K19/2RGC001759 K19/2RGC001627	Square chip: 1/10W, 470 KohmJ	R62	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ			
R9	K19/2RGC001627 K19/2RGC001643	Square chip: 1/10W, 10 KohmJ	R63		NOT USED			
R10	K19/2RGC001502	Square chip: 1/10W, 100 KohmJ Square chip: 1/10W, 10 KohmJ	R64	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ			
R11	K19/2RGC004126	Square chip: 1/10W, 15 KohmJ	R65	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ			
R12	K19/2RGC001528	Square chip: 1/10W, 100 ohmJ	R66	K10/2RGC001627	Square chip: 1/10W, 10 KohmJ			
R13	K19/2RGC004647	Square chip: 1/10w, 3.9 KohmJ	R67	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ			
R14	K19/2RGC001601	Square chip: 1/10W, 3.3 KohmJ	R68	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ			
R15	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ	R69	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ			
R16	K19/2RGC001759	Square chip: 1/10W, 470 KohmJ	R70	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ			
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	SYMBOL	GE PART NO.	DESCRIPTION
I	R71	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
l	R72	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
l	R73	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
l	R74	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
١	R75	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
ı	R76	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
l	R77	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
١	R78	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
ı	R79	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
ı	RSO	K19/2RGC001916	Square chip: 1/10W, 27 KohmJ
١	R81	K19/2RGC004035	Square chip: 1/10W, 56 KohmJ
l	R82	K19/2RGC004621	Square chip: 1/10W, 120 KohmF
١	R83	K19/2RGC001825	Square chip: 1/10W, 220 KohmJ
i	R84	K19/2RGC001759	Square chip: 1/10W, 470 KohmJ
1	R85	K19/2RGC001528	Square chip: 1/10W, 100 ohmJ
1	R86	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
1	R87	K19/2RGC001528	Square chip: 1/10W, 100 ohmJ
	R88 and R89	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
	R90	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ
l	R91 and R92	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
l	R93	K19/2RGC001759	Square chip: 1/10W, 470 KohmJ
	XY1	K19/2YYZ001062	RUBBER DAMPER
	¥1	K19/2YAA181756	

PARTS LIST

PARTS LIST

LBI-31909 M-PD 16 PLUS SPEAKER BOARD

SYMBOL	GE PART NO.	DESCRIPTION
O I MDUL	GE FART NU.	DESCRIPTION
		INTEGRATED CIRCUITS
201	K19/2AAJ016017	Audio Processor, STC9140F
202	K19/2AAB004284	OP Amp, uPC451G2-T1
203	K19/2AAE053023	VTG-REG, S-81250HG-RD-T1
204	K19/2AAC004135	OP Amp, uPC393G2-T1
215	K19/2CAK005909	Ceramic chip: 100 pF, 50V
230	K19/2CCF002072	Tantalum: 1 uF, 16V
231	K19/2CAK005818	Ceramic chip: 22 pF, 50V
nd 232		
233	K19/2CAK013127	Ceramic chip: 1000 pF, 50V
234	K19/2CCF002072	Tantalum: 1 uF, 16V
235	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
236	K19/2CCF002163	Tantalum: 0.33 uF, 25V
237	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
ad 236		
239	K19/2CAK013192	Ceramic chip: 4700 pF, 50V
240	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
241	K19/2CAK013010	Ceramic chip: 0.1 uF, 25V
7343	K19/2CAK013119	Ceramic chip: 0.01 uP, 50V
344	ļ	
7045	1	NOT USED
700	K19/2CCP002080	Tantalum: 2.2 uF, 16V
347	K19/2CAK013127	Ceramic chip: 1000 pP, 50V
240		NOT USED
340	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
300	K19/2CAK013135	Ceramic chip: 0.015 uP, 50V
361	K19/2CAK013119	Ceramic chip: 0.01 uP, 50V
200	K19/2CAK013010	Ceramic chip: 0.1 uF, 25V
7863	K19/2CAK005909	Ceramic chip: 100 pF, 50V
7864	K19/2CAK013119	Ceramic chip: 0.01 uF, 50V
7204	K19/2CAK013127	Ceramic chip: 1000 pF, 50V
294	K19/2CCF006024	Tantalum: 6.8 uF, 10V
287		NOT USED
256	K19/2CAK013010	Ceramic chip: 0.1 uP, 25V
C250	K19/2CAK013119	Ceramic chip: 0.01 uP, 50V
260		NOT USED
261	K19/2CAK013226	Ceramic chip: 470 pF, 50 V
		DIODES
R201	K19/2QBE005024	DAP202KT-96
P1	K19/	BBL-113-G-E
P2	K19/	BBL-109-G-E
P3	K19/	BBL-105-G-E
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SYMBOL	GE PART NO.	DESCRIPTION
Q200	K19/2QAD001034	28C2462LCTL
Q201		NOT USED
Q202	K19/2QAD004103	2SB798T1D1
Q203	K19/2QAD001026	28A11219BTL
Q204	K19/2QAD001034	2SC2462LCTL
Q205	K19/2QAD004103	2SB798T1D1
Q206	K19/2QAD001026	2SA1121SBTL
R201	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
R202	K19/2RGC004035	Square chip: 1/10W, 56 KohmJ
R203	K19/2RGC004449	Square chip: 1/10W, 150 KohmJ
R204	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
R205	K19/	Square chip: 1/10W, 191 KohmF
R206	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
R207	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
and R208		
R209	K19/2RGC001783	Square chip: 1/10W, 3.3 MohmJ
R210 and	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
R211		
R212	K19/2RGC004670	Square chip: 1/10W, 1 KohmF
R213	K19/2RGC001874	Square chip: 1/10W, 10 KohmF
R214	K19/2RGC001635	Square chip: 1/10W, 22 KohmJ
R215	K19/	Square chip: 1/10W, 105 KohmF
R216	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
R217	K19/2RGC001726	Square chip: 1/10W, 47 KohmJ
R218	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
R219	K19/2RGC004308	Square chip: 1/10W, 390 ohmJ
R220	K19/2RGC001502	Square chip: 1/10W, 10 ohmJ
R221 R222	K19/2RGC001726	NOT USED Square chip: 1/10W, 47 KohmJ
R223	K19/2RGC001/28	Square chip: 1/10W, 47 konmJ
R224	K19/2RGC001932	Square chip: 1/10W, 100 KohmF
and R225	,	
R226	K19/2RGC001593	Square chip: 1/10W, 2.2 KohmJ
R227	K19/2RGC001726	Square chip: 1/10W, 47 KohmJ
R228	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ
R229	K19/2RGC001833	Square chip: 1/10W, 2.2 ohmK
R230	K19/2RGC001726	Square chip: 1/10W, 47 KohmJ
R231	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
R232	K19/2RGC001585	Square chip: 1/10W, 1 KohmJ
R233	K19/2RGC001759	Square chip: 1/10W, 470 KohmJ
R234	K19/2RGC001825	Square chip: 1/10W, 220 KohmJ
R235	K19/2RGC001635	Square chip: 1/10W, 22 KohmJ
R236	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
R237 and R238	K19/2RGC001932	Square chip: 1/10 , 100 KohmP
R239	K19/2RGC004688	Square chip: 1/10W, 240 KohmF
R240	K19/	Square chip: 1/10W, 191 KohmP
R241	K19/	Square chip: 1/10W, 12.4 KohmP
R242 and R243	K19/2RGC001874	Square chip: 1/10♥, 10 KohmF

SYMBOL	GE PART NO.	DESCRIPTION
R244	K19/2RGC001643	Square chip: 1/10W, 100 KohmJ
R245	K19/2RGC001833	Square chip: 1/10W, 2.2 ohmK
R246		NOT USED
R247	K19/2RGC004696	Square chip: 1/10W, 1.2 MohmJ
R248	K19/2RGC001775	Square chip: 1/10W, 1 MohmJ
R249	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
R250	K19/2RGC001791	Square chip: 1/10W, 10 MohmK
R251	K19/2RGC001627	Square chip: 1/10W, 10 KohmJ
R252	K19/2RGC001577	Square chip: 1/10W, 680 ohmJ
XY201	K19/2YYZ001062	
Y201	419/2YAA181814	8.00 MHz, A4WX01733
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^{*}COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES